

Intermittent Flow in Microcrystal Plasticity

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Acknowledgments:

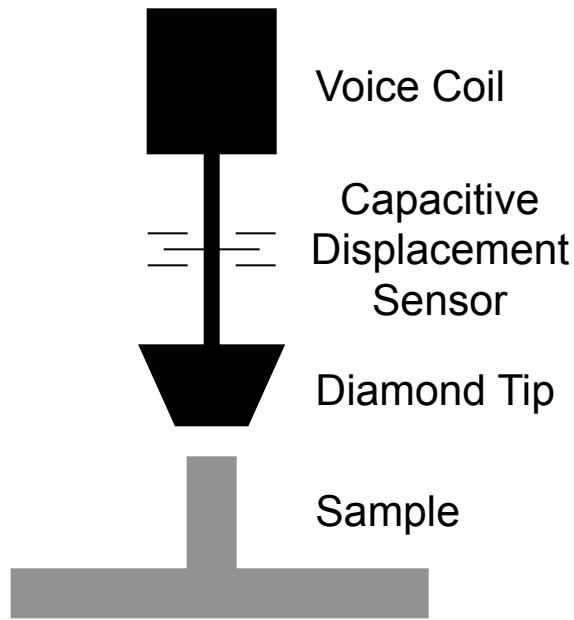
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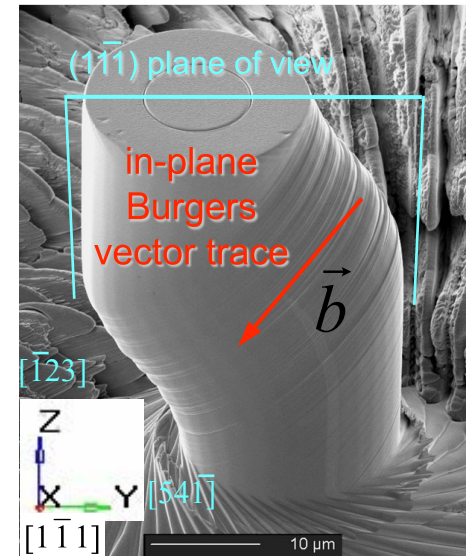
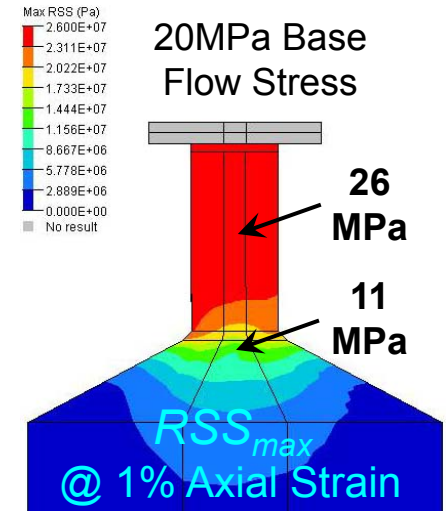
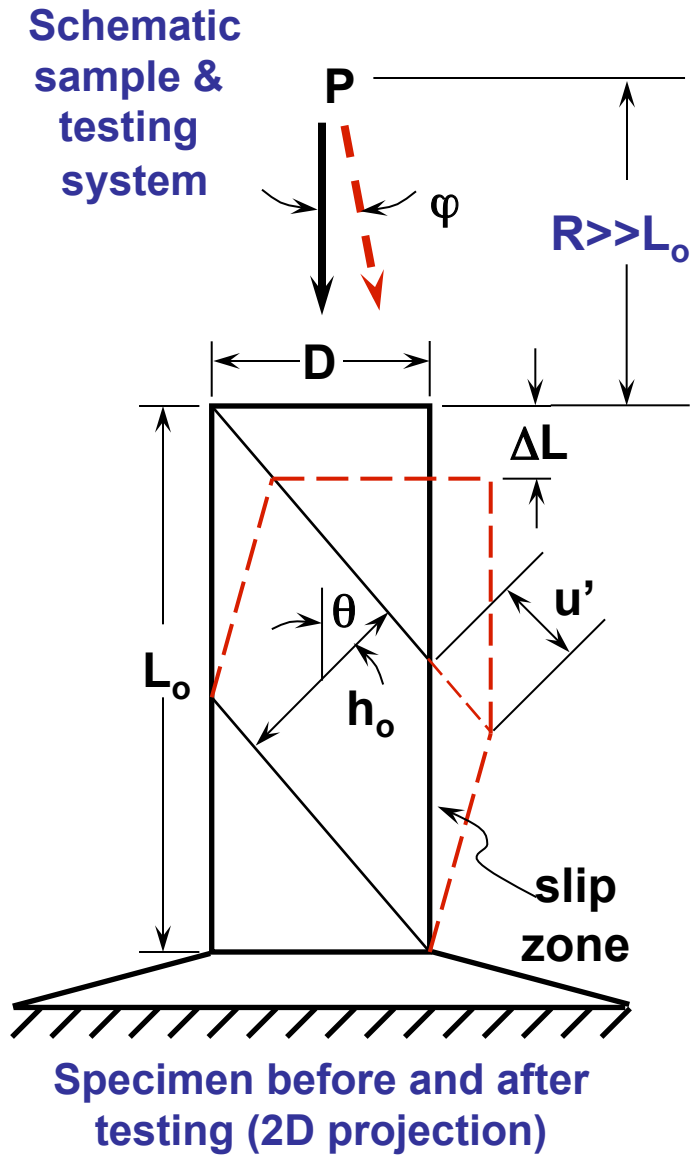
Outline

- Some Comments on Understanding Microcrystals
- Strain Intermittency in LiF Microcrystals ($\rho_o \sim 10^9/\text{m}^2$)
- Strain-Rate Effects on Intermittency in Ni Microcrystals ($\rho_o \sim 10^{12}/\text{m}^2$)
- Initial Studies of Strain Intermittency via 3d-DD Simulations ($\rho_o \sim 10^{12}/\text{m}^2$ to $\rho_o \sim 10^{13}/\text{m}^2$)
- Selected Current Work & Future Directions ($\rho_o \sim 10^{15}/\text{m}^2$)

Testing Device, Samples & Response



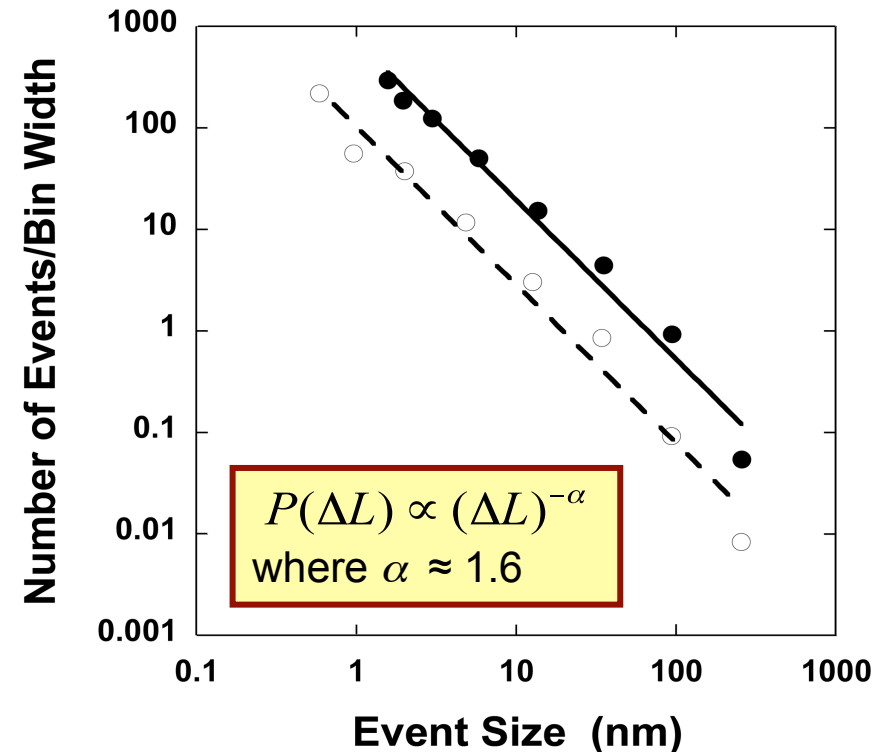
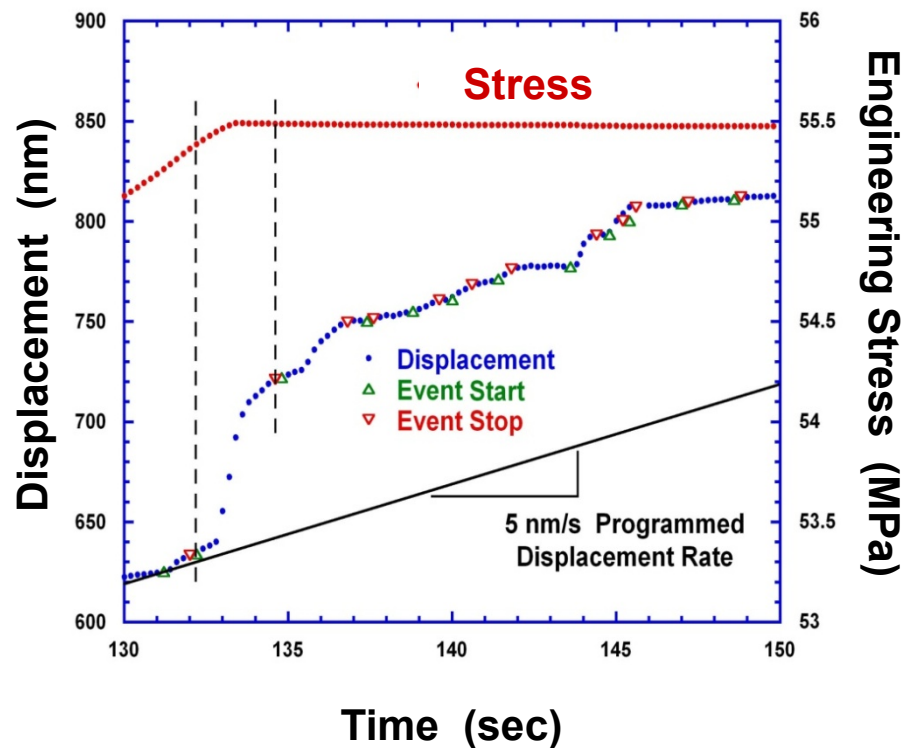
Attributes of Nanoindenter
 Displacement range: 500 μm
 “ “ resolution: 0.02 nm
 ($\Delta\epsilon \sim 0.6 \mu\epsilon$)
 Maximum load: 500 mN
 ($\sigma_{\text{max}} \sim 6.3 \text{ GPa}$)
 Load resolution: 50 nN
 ($\Delta\sigma \sim 0.0006 \text{ MPa}$)



CP-FEM Simulation & SEM image
 20 μm Ni sample

Intermittency & “Avalanche” Slip Events

*Pure Ni, <-269> orientation, Stage I; 9 samples, 20-30 μm dia.; $\dot{\epsilon} = 1.1 \times 10^{-4}/\text{s}$



- Analysis methods somewhat ad hoc...
- Driving forces and control mechanisms unknown
- Basis for largest observed avalanche ?
- Temporal scaling ?
- Basis for stochastic plasticity framework ?

Avalanche Exponents vs Strain Rate

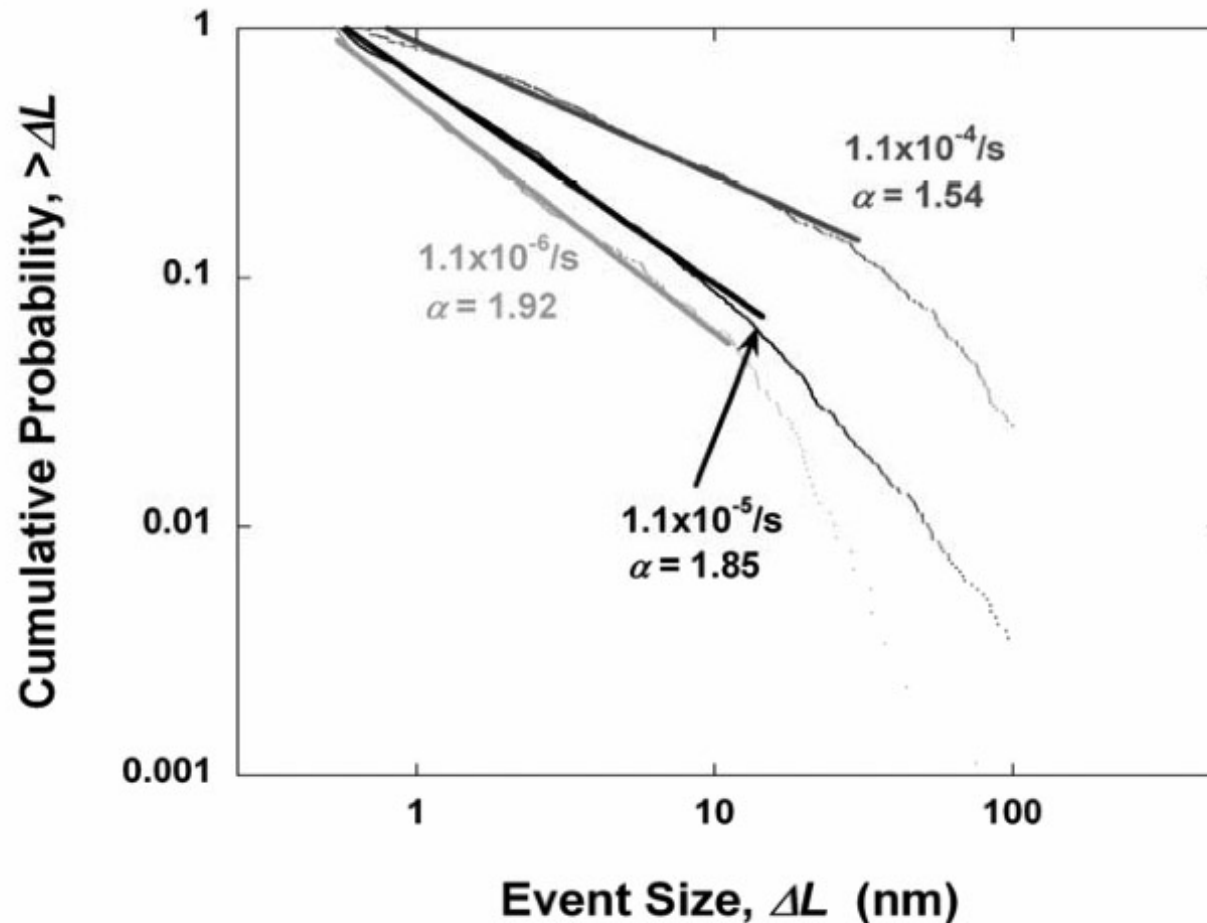


Fig. 3: Cumulative probabilities for avalanche events exceeding a given size, versus size, for three different loading rates. Data are for $\langle -269 \rangle$ oriented, $\sim 20 \mu\text{m}$ diameter Ni crystals.

Selected Issues for Dislocation Avalanches

- Large avalanches expected to contribute largest part of strain in any experiment; not seen for large specimens—why not?
- What is and what controls the avalanche cut-off (a correlation length)?
 - Zaiser, et al, (2007), Theory: X_{max} proportional to Sample 'Size' (L), Machine Stiffness (M) & Hardening Rate (Θ)
 - Weiss, et al, (2008) Experiment & Theory: X_{max} proportional to L & M ; Θ does not matter

- What about other experimental details?
 - Pole sources in microsamples (few limits on X_{max})
 - Variations in initial dislocation density?
 - Creep loading excludes M (nearly constant far-field driving force)
 - For low dislocation density, Θ tends to zero
 - ... X_{max} in small samples may only be limited by test boundary conditions
- Strain rate effects in 'rate-insensitive' FCC metals?

Demands better analysis methods & better models/simulations

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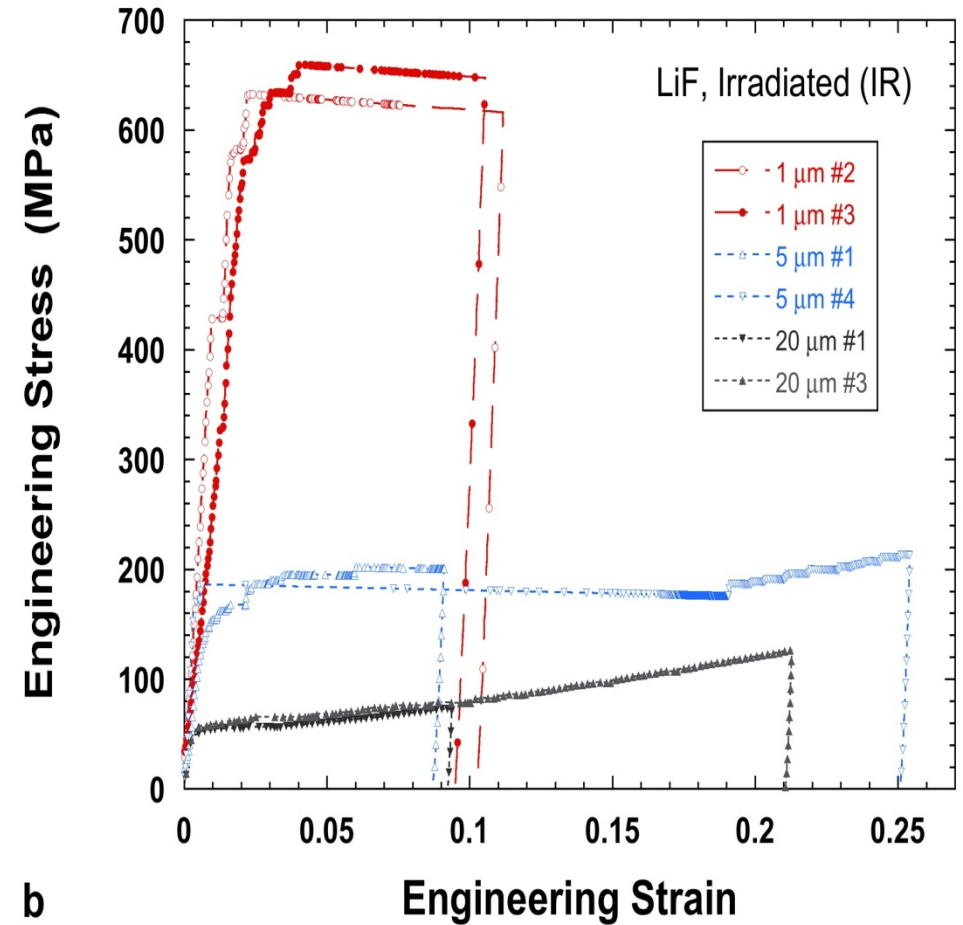
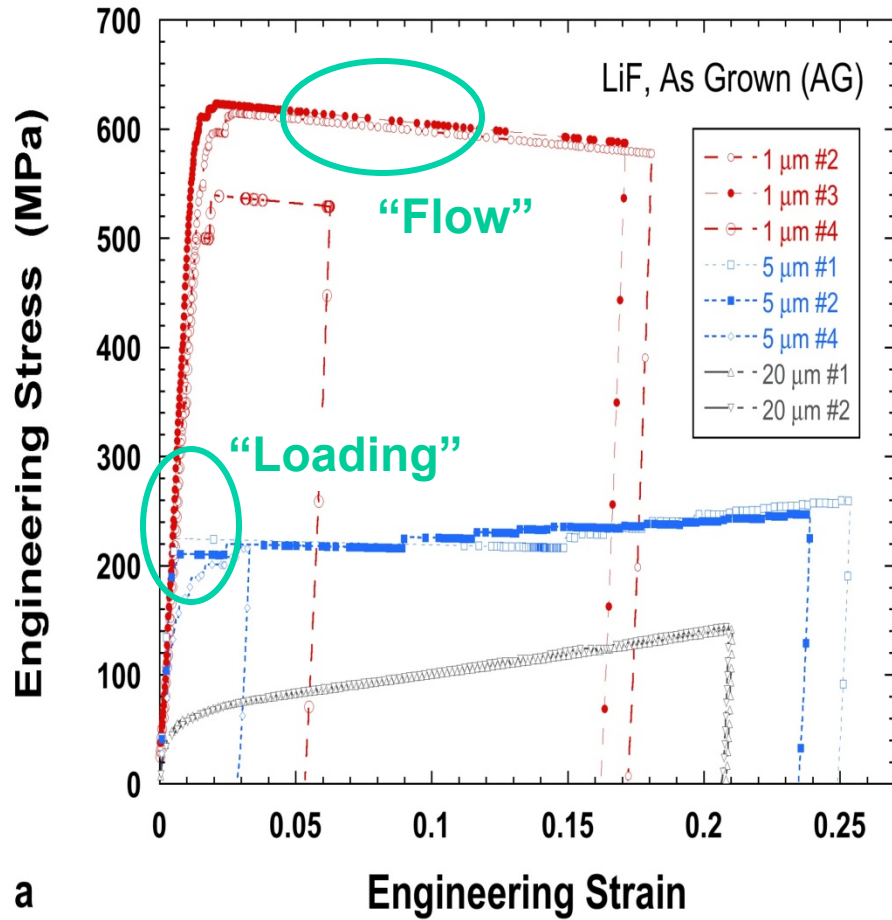
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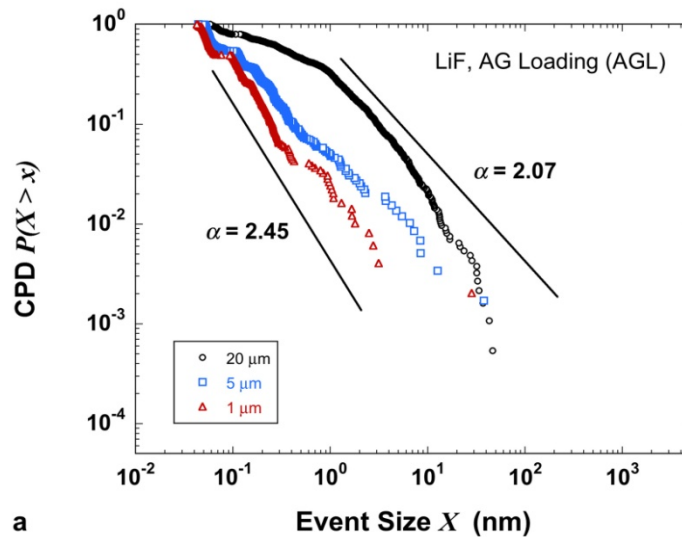
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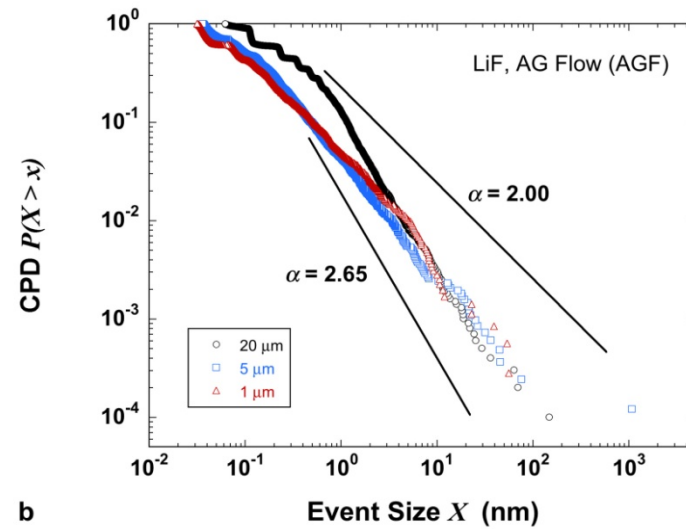
LiF Microcrystal Stress-Strain Curves



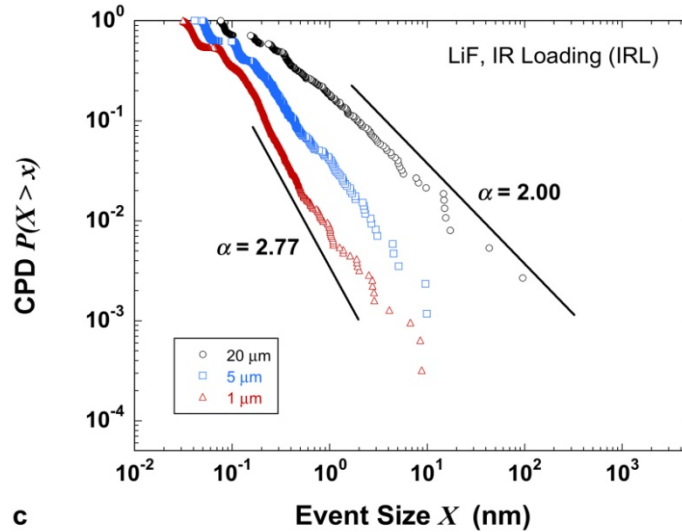
Platen Displacement Burst (Size) Probability



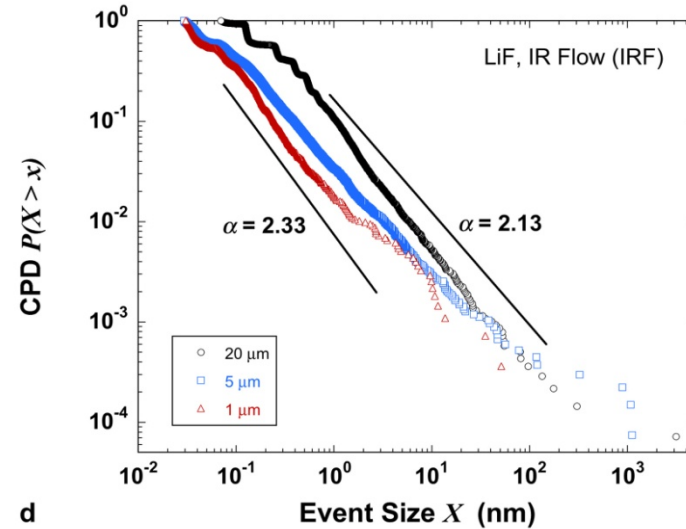
a



b



c

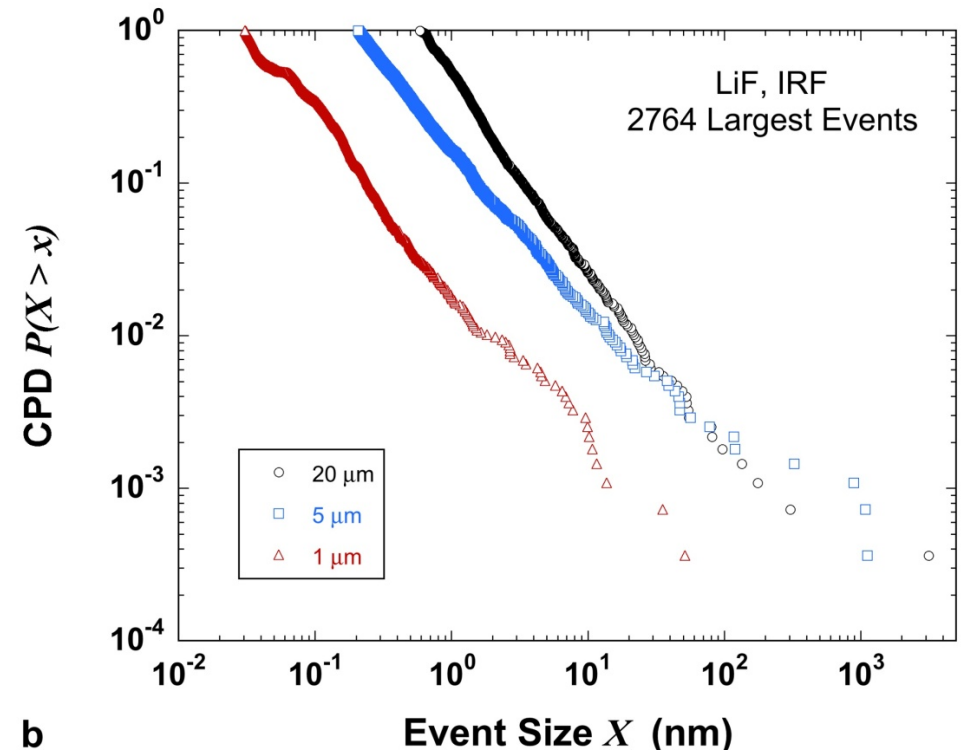
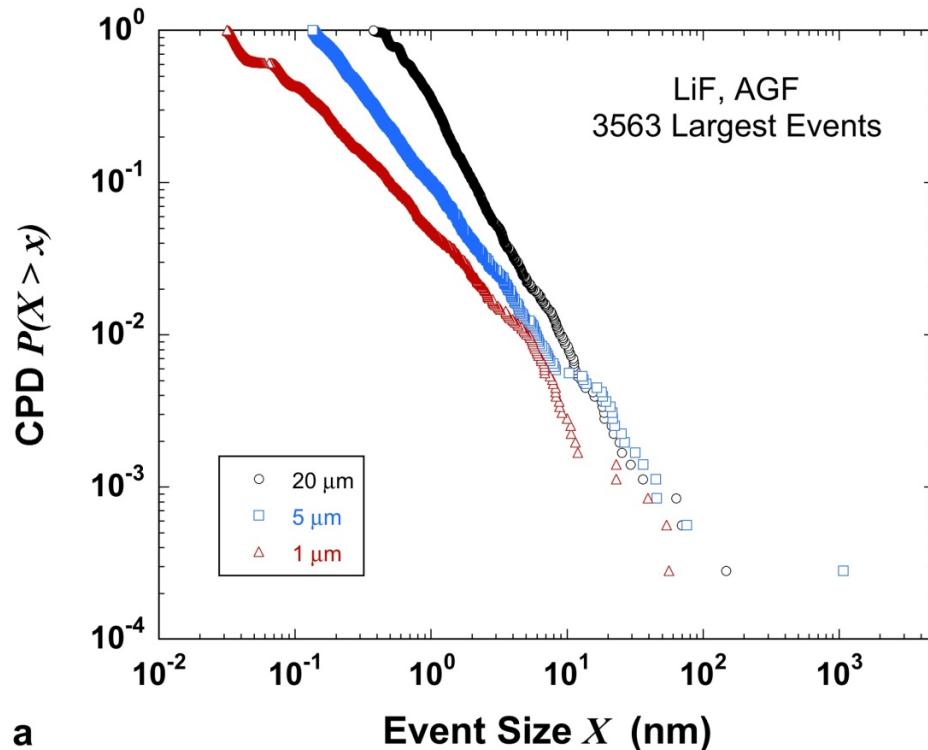


d

Well-behaved power laws, MLE scaling exponents consistently > 1.5

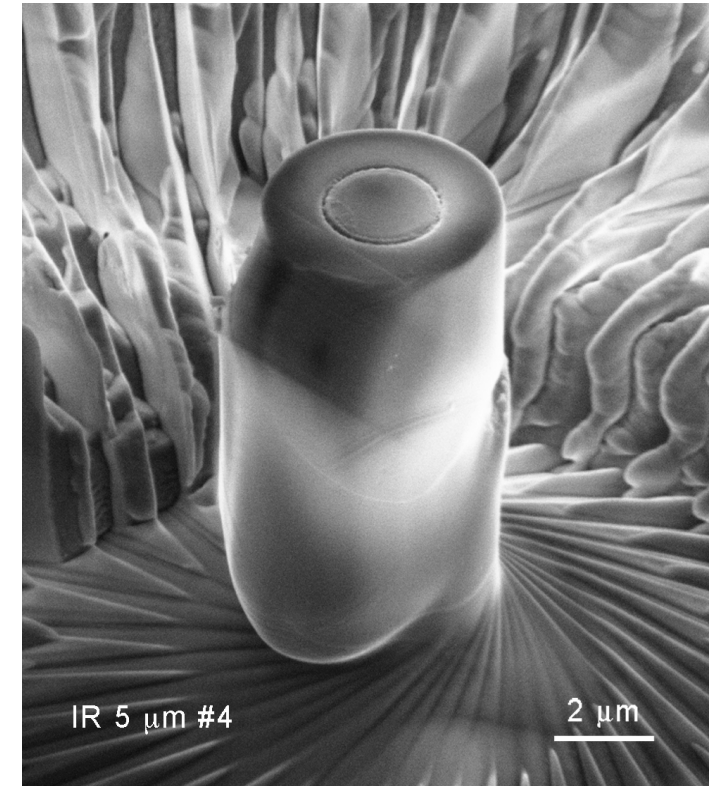
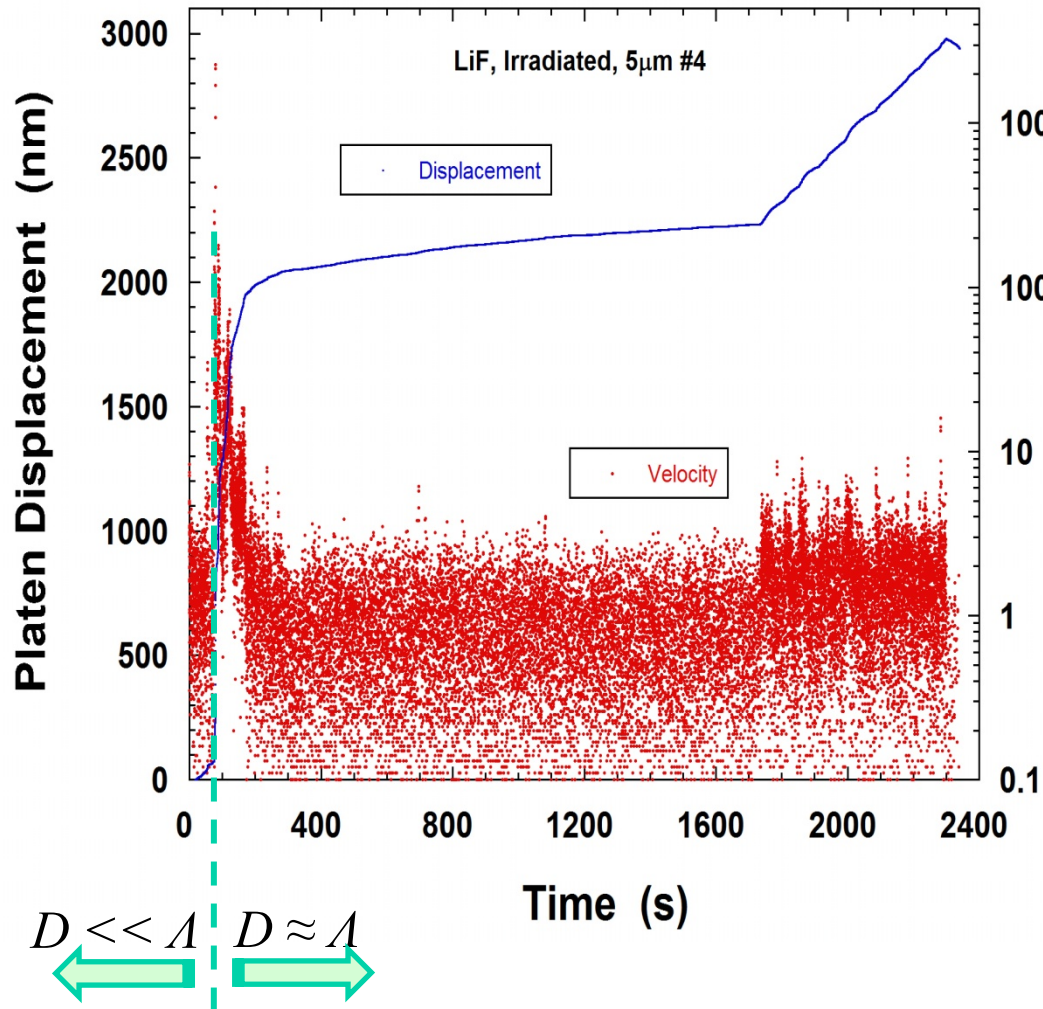
Sample Size Effect on Strain Bursts

Normlized rank order statistics



- Probability of events at a given size decreases in small samples
- Probability of maximum size not so different
- Scaling exponents tend to decrease slightly for small samples

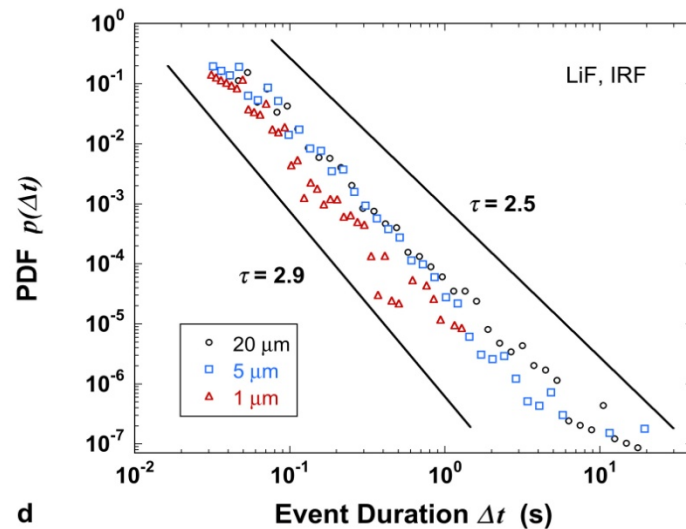
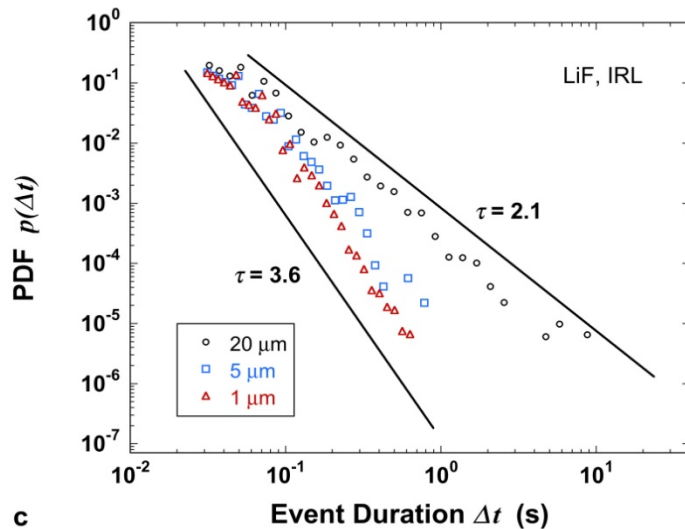
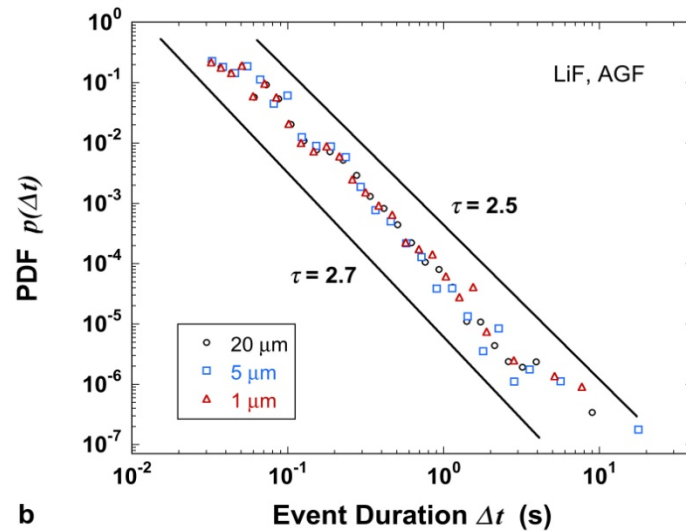
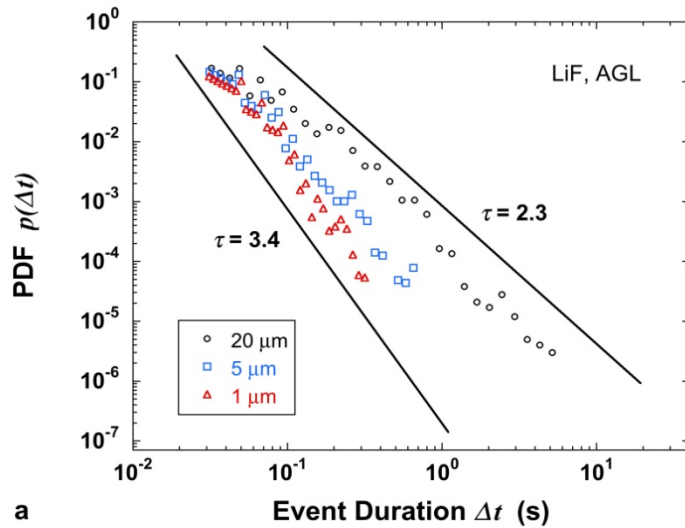
Largest Strain Events in LiF: $\rho_0 < 10^9/m^2$



Intersecting slip zones in deformed microcrystal

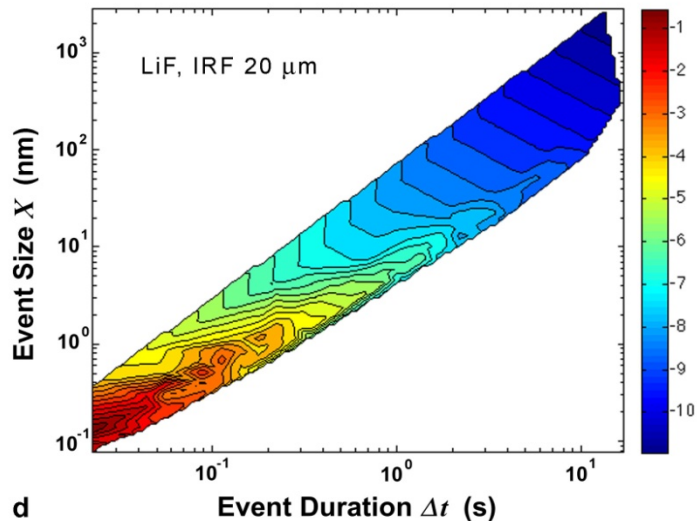
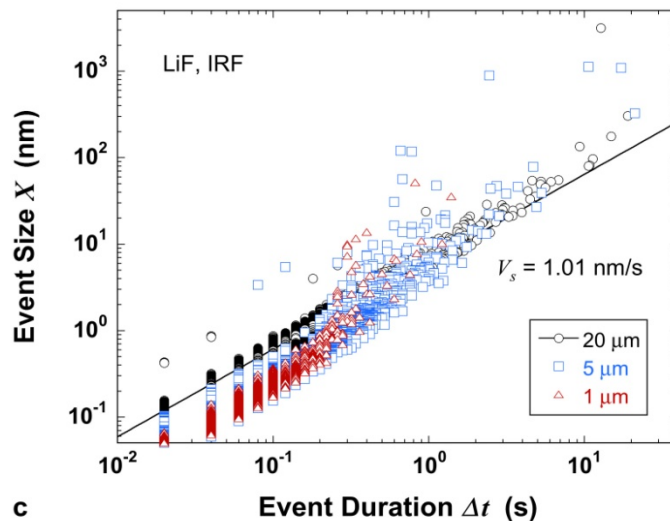
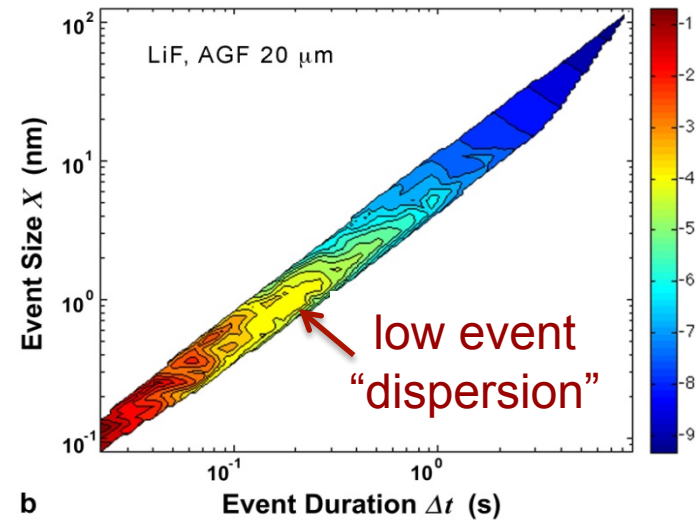
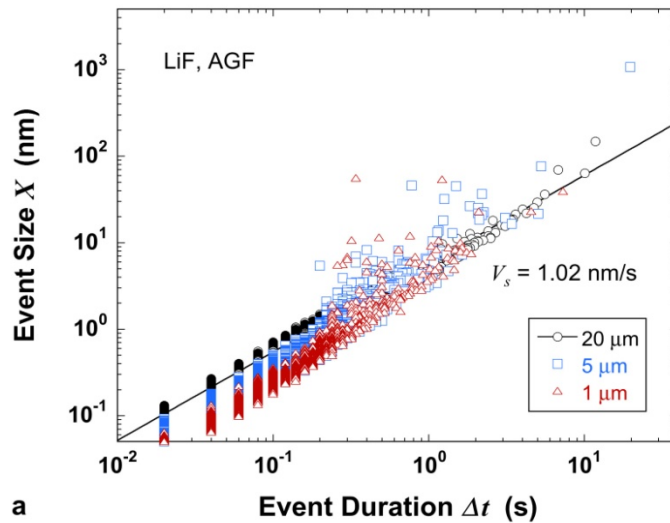
Large bursts occur at transition from “multiplication limited” loading to flow

LiF Strain Burst Durations Also Show Scaling



Duration power law scaling exponents consistently >2

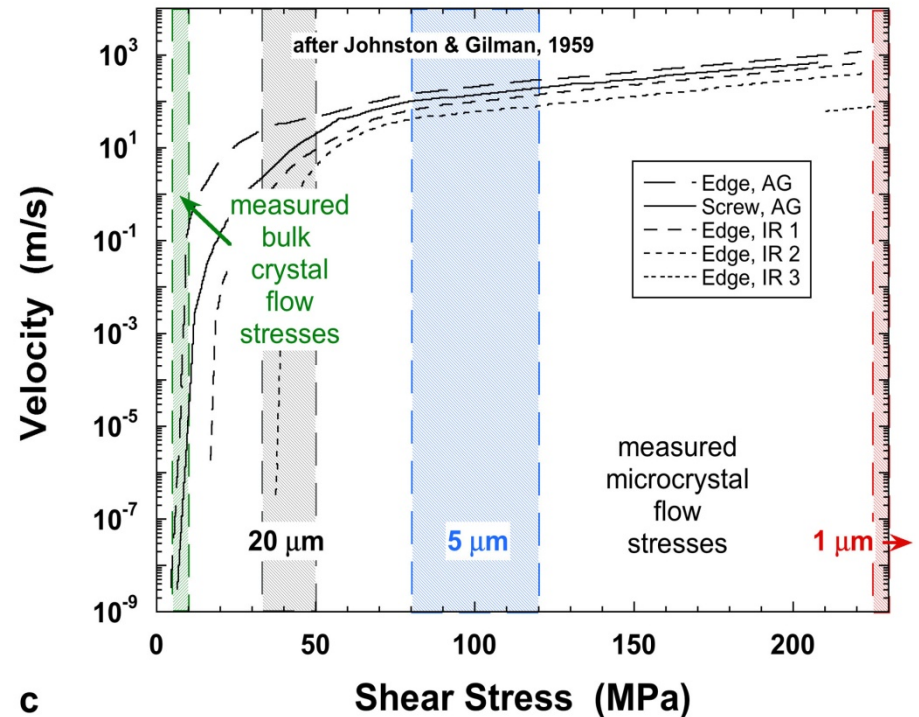
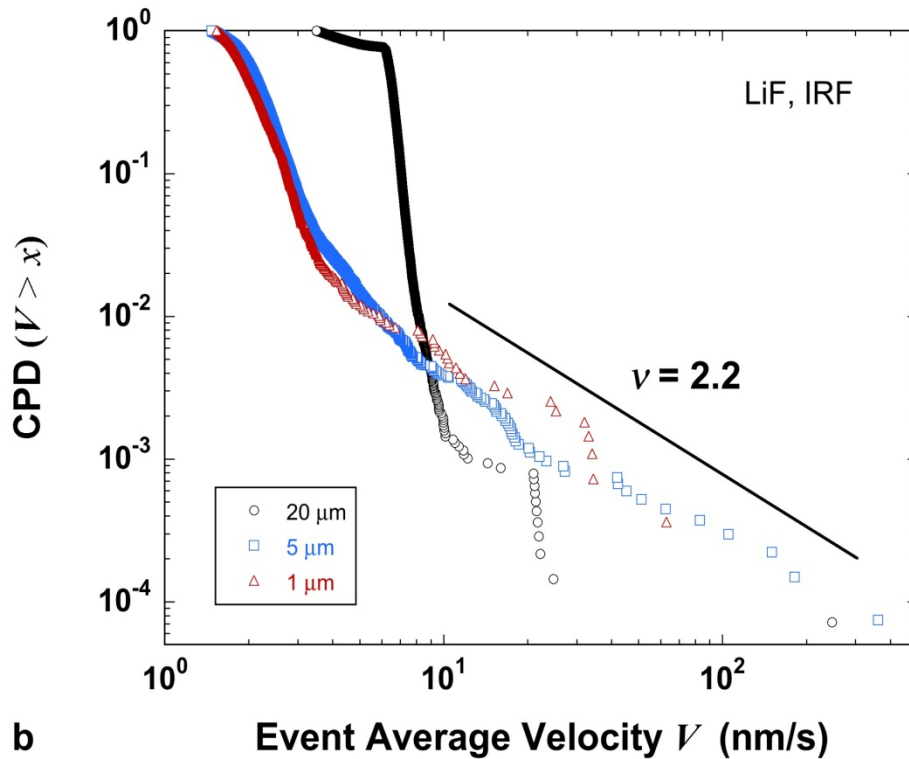
Joint Burst Size – Duration Probabilities



Most event sizes proportional to their duration; large events are exceptions

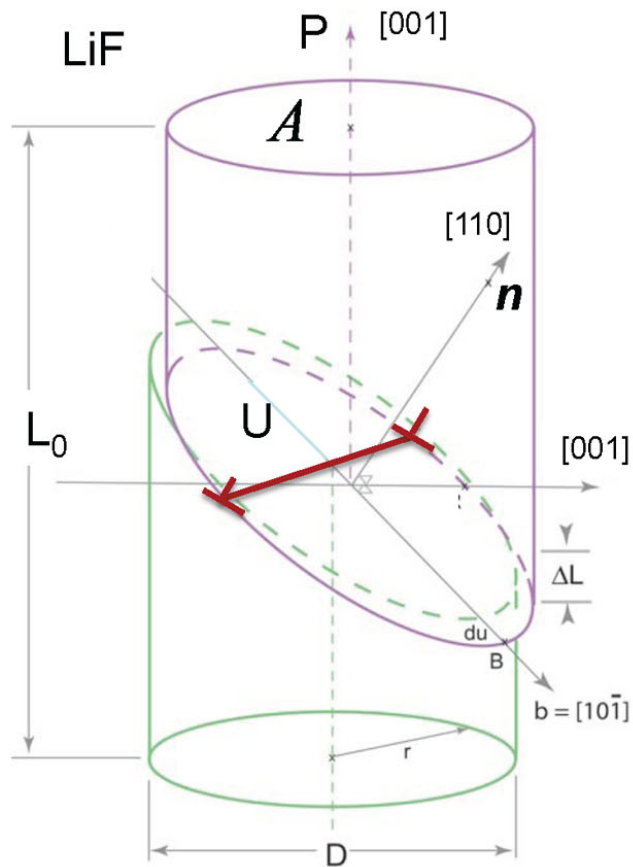
Avalanche Velocity vs Dislocation Velocity

Mismatch observed between platen vs dislocation velocities



Experiments may not directly reveal dislocation temporal dynamics

Dislocation Velocity & Platen Velocity Estimates



For single straight dislocation moving slip distance, U

$$D = 2.015 \times 10^{-6} \text{ m}$$

$$U = 2.85 \times 10^{-6} \text{ m}$$

$$dU = |b| = 2.85 \times 10^{-10} \text{ m}$$

$$v_d = 2.85 \text{ m/s}$$

Time for displacement ΔL

$$t_U = U / v_d = 1 \times 10^{-6} \text{ s}$$

$$\Delta L = |b| / \sqrt{2} = 2.015 \times 10^{-10} \text{ m}$$

Net platen velocity for displacement ΔL

$$v_p = \Delta L / t_U = 2.015 \times 10^{-4} \text{ m/s}$$

$$v_p = 2.015 \times 10^5 \text{ nm/s}$$

For single arm source traversing circumference, C

$$C \approx 2\pi \sqrt{\frac{a^2 + b^2}{2}} = 2\pi \sqrt{\frac{(2.015 \times 10^{-6})^2 + (2.85 \times 10^{-6})^2}{2}} = 1.55 \times 10^{-5} \text{ m}$$

$$t_C = C / v_d = 5.44 \times 10^{-6} \text{ s}$$

$$v_p = \Delta L / t_C = 3.704 \times 10^{-5} \text{ m/s}$$

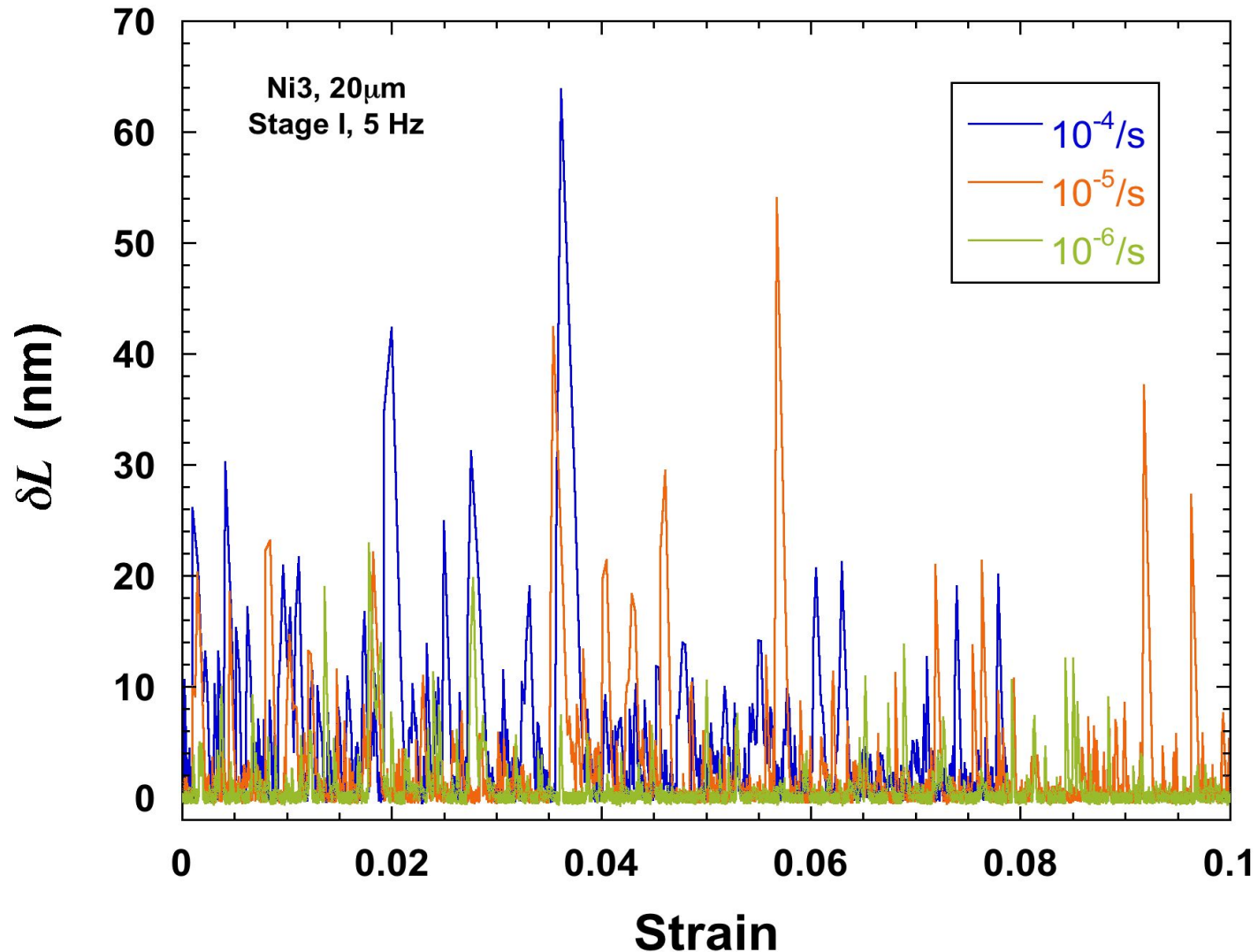
$$v_p \approx 3.7 \times 10^4 \text{ nm/s}$$

Maximum measured platen velocity for 1 & 5 μm samples (50 Hz data) : $\sim 3.7 \times 10^2 \text{ nm/s}$

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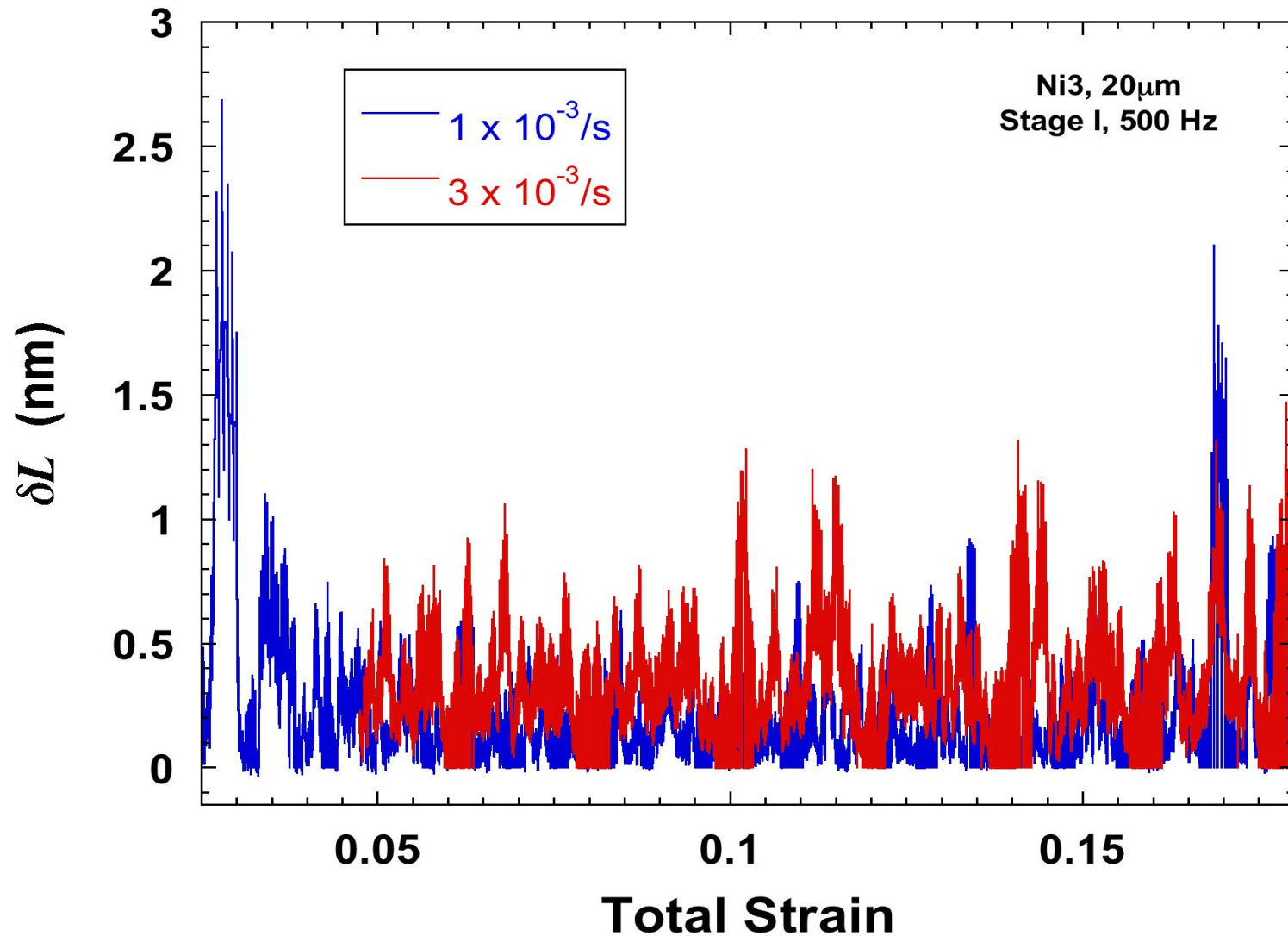
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Ni Strain (Time) Series Comparisons



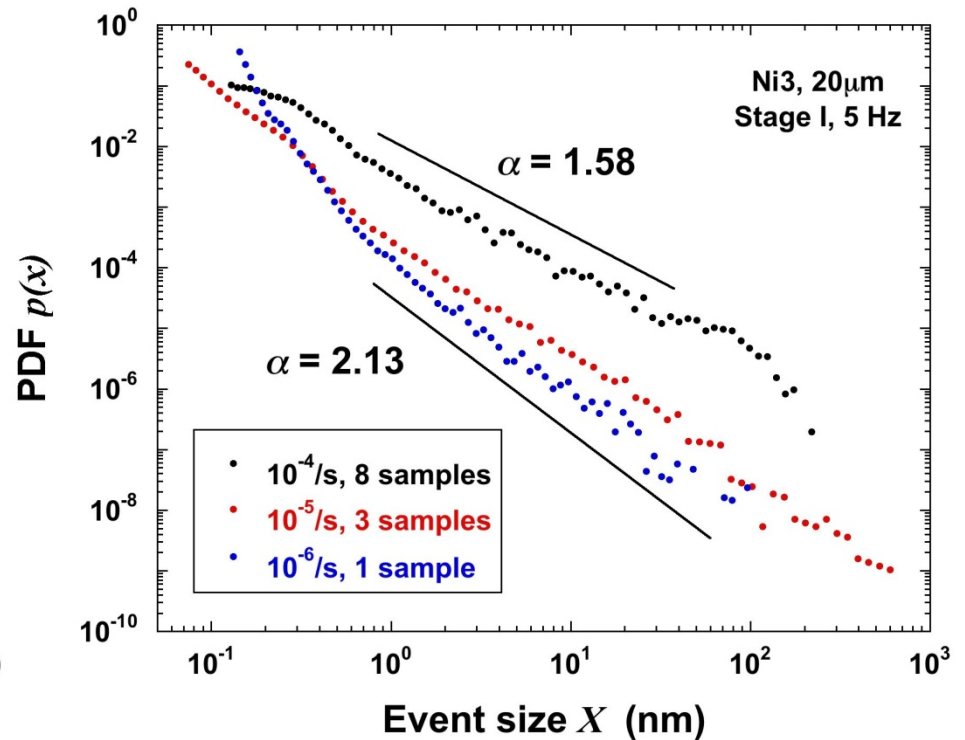
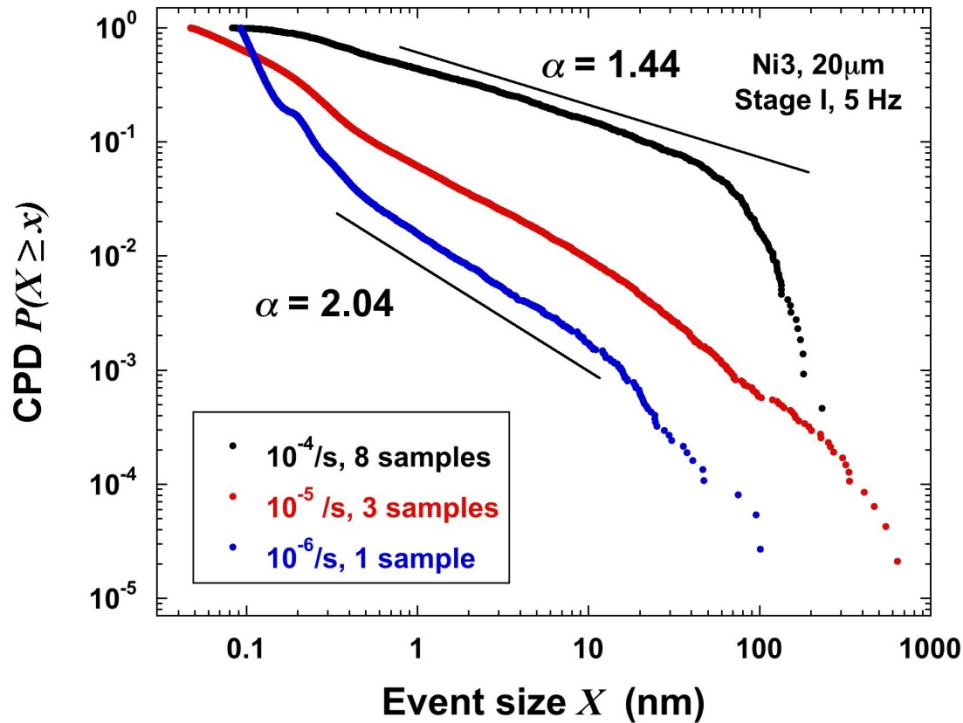
Qualitative differences in average & largest sizes; frequency per unit strain

Ni Strain (Time) Series for High Strain Rates



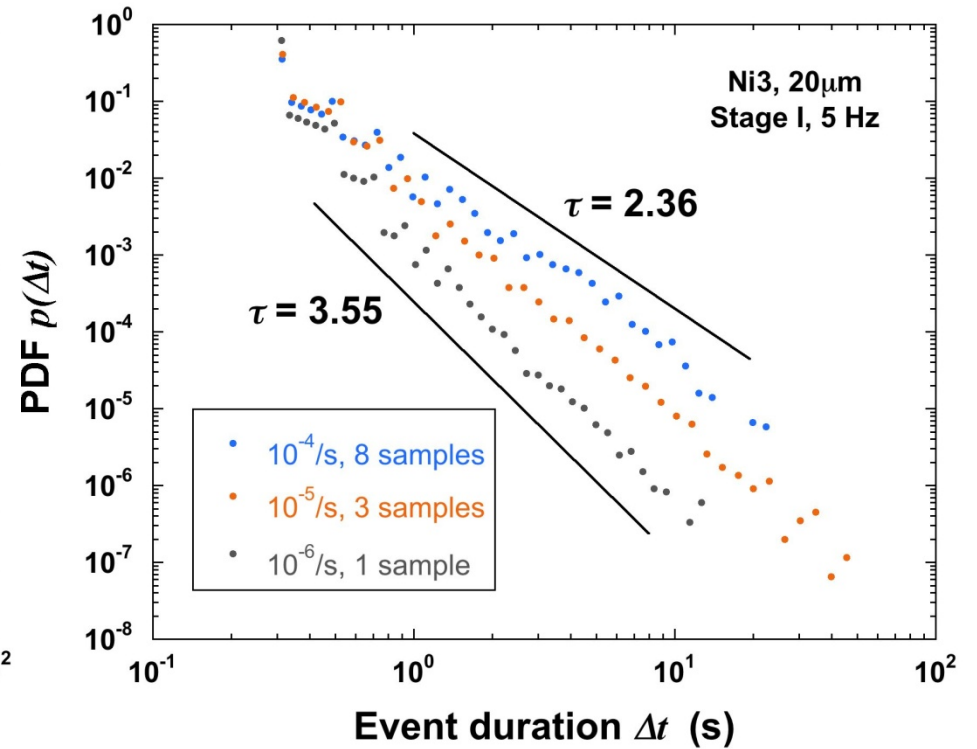
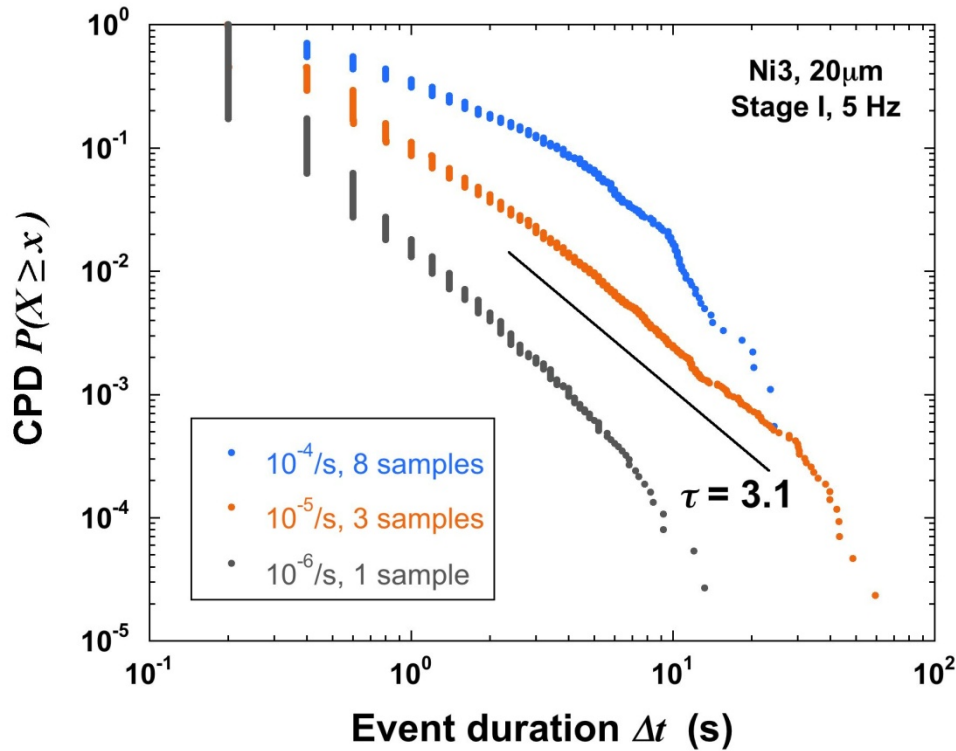
Overlapping avalanches for both strain rates

Pure Ni: Effect of Strain Rate on Burst Size Scaling



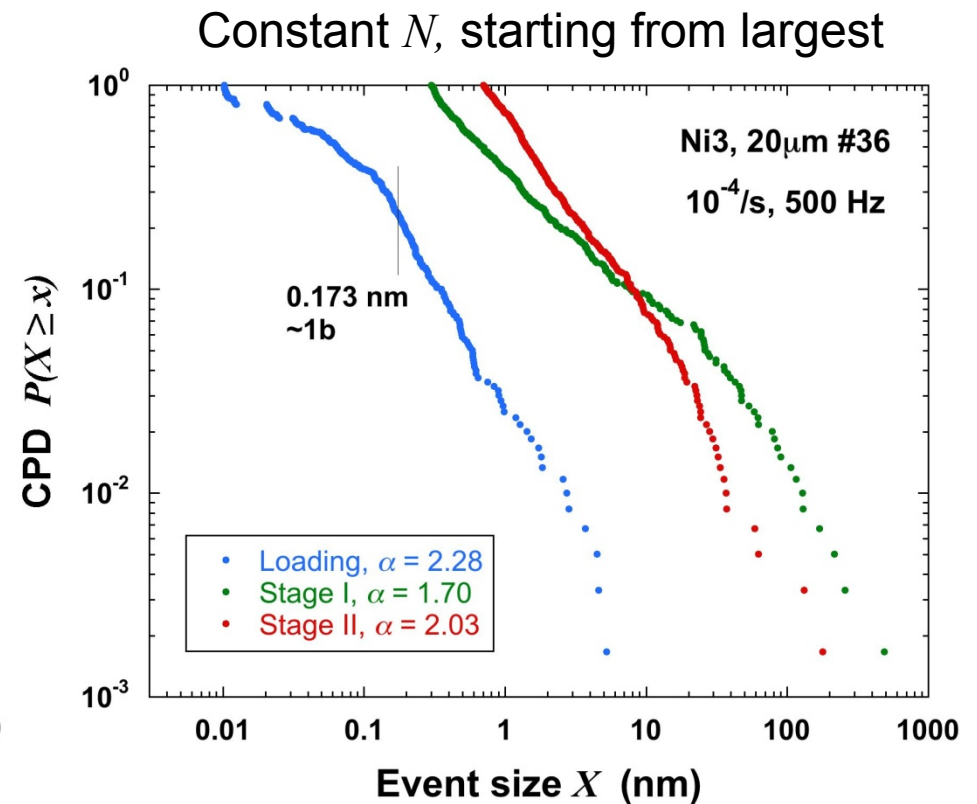
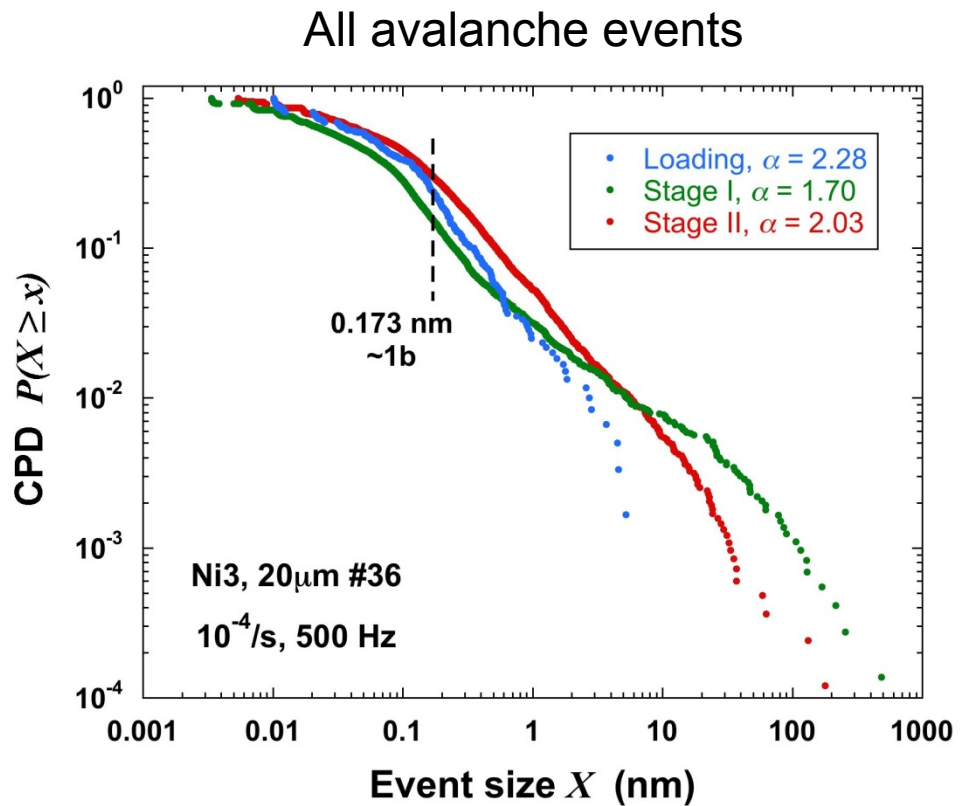
Avalanche size scaling exponents clearly rise above 1.5 at low strain rates

Pure Ni: Effect of Strain Rate on Burst Durations



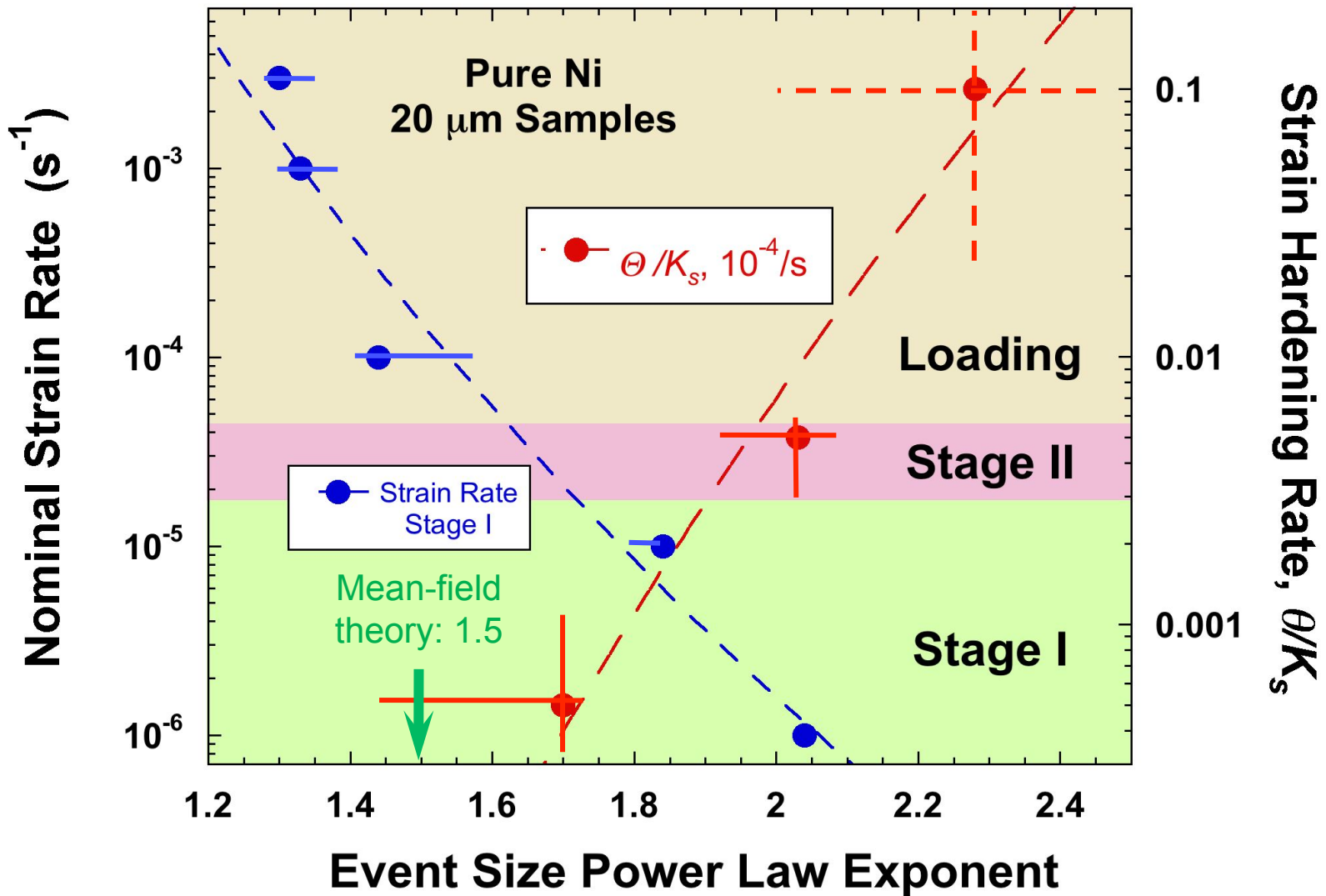
Avalanche duration scaling exponents clearly rise above 2.0 at low strain rates

Effect of Deformation Stage of Ni on Size Scaling



Avalanche scaling exponent depends upon deformation regime

Scaling Exponent vs Strain Rate & Hardening Rate

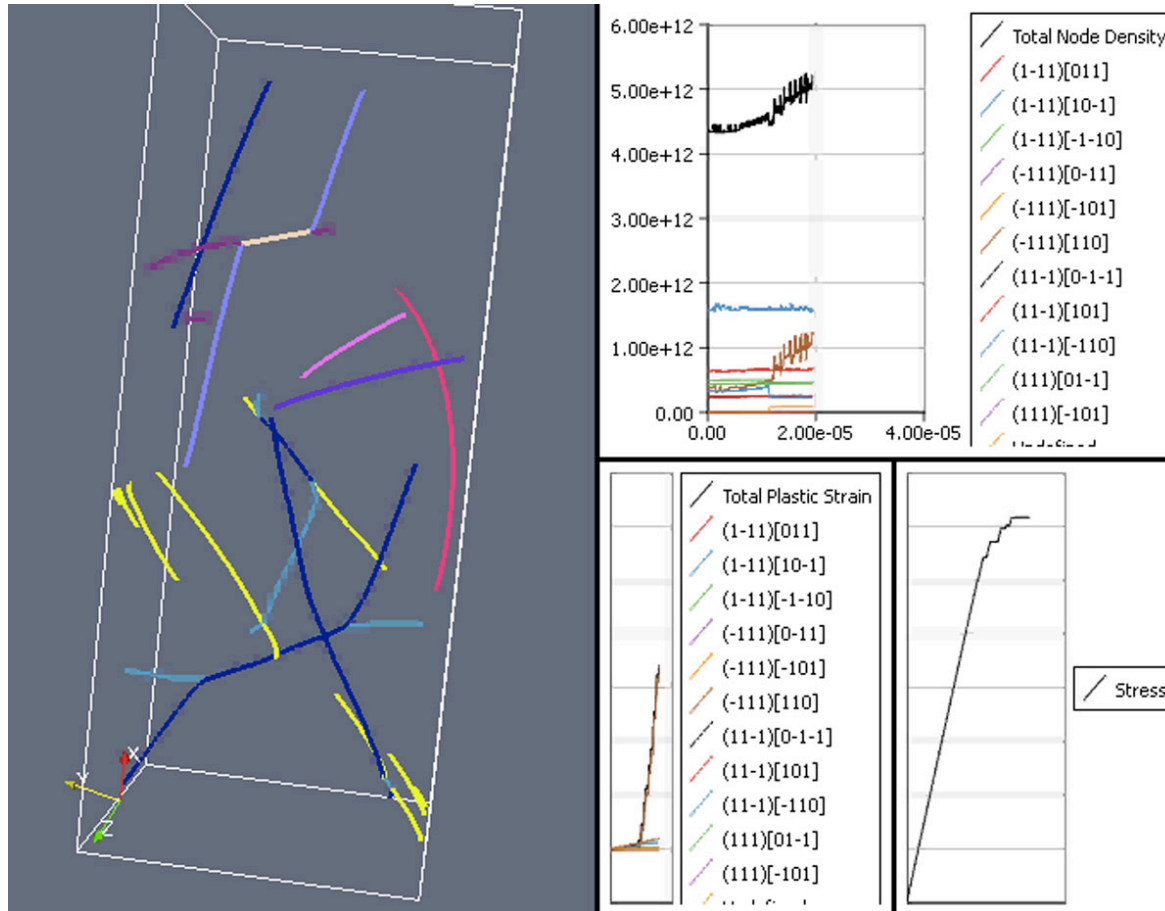


Significant deviations from mean-field theory of scale-invariance

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3d Dislocation Dynamics Simulations of 1 μm Cells



<001>-type, 1 μm cell faces, $L_o/D = 2.5$

Loading is “experimental mode” along [4-13]

Schmid factor is $m = 0.471$ for primary (111)[1-10]

Starting dislocation density $\rho_o = \sim 2 \times 10^{12}/\text{m}^2$

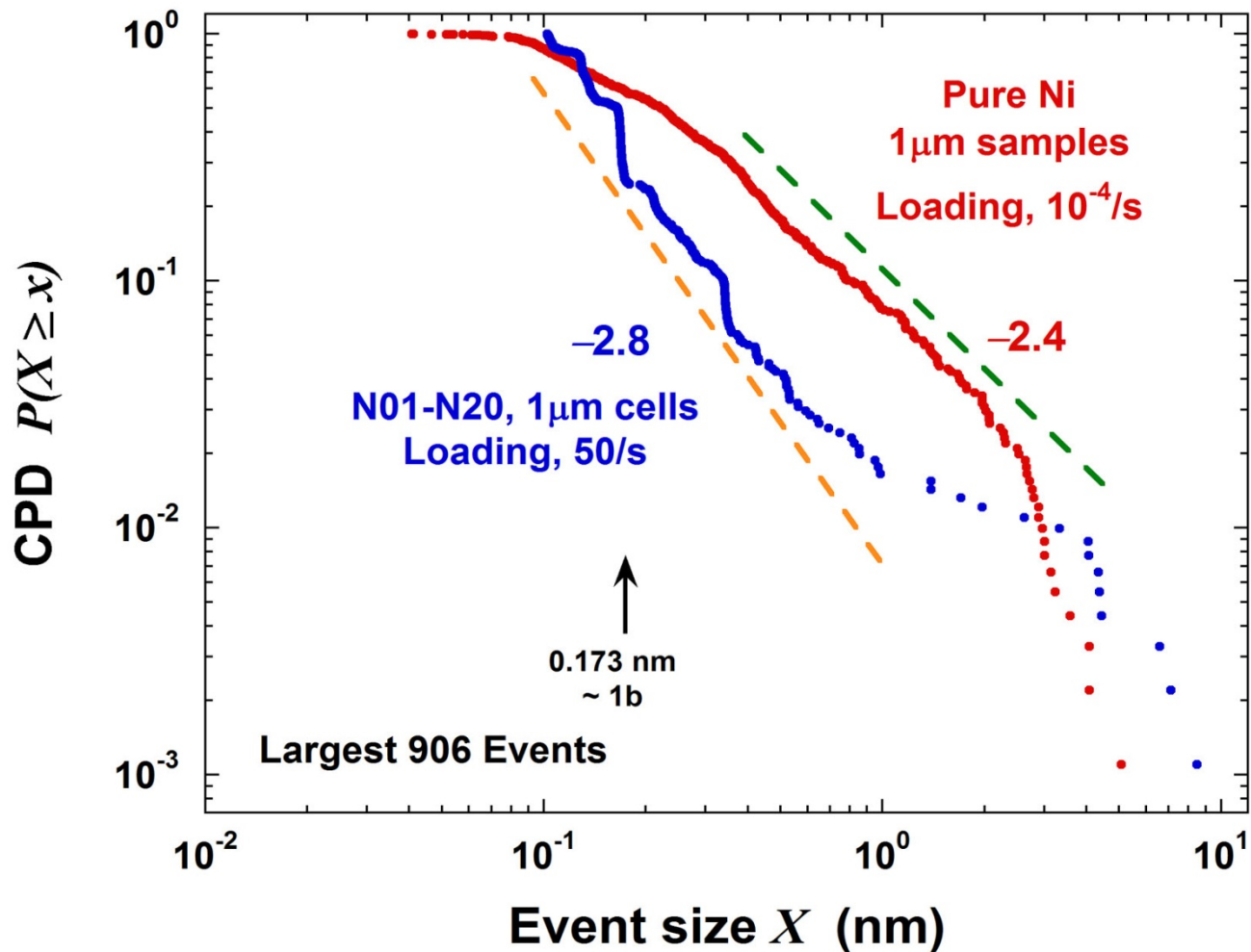
$\dot{\epsilon} = 50/\text{s}$, parameters for Ni

20 random instantiations

How best to “integrate” avalanche events remains an open question
Also strain rates, cross-slip models (thermal activation), strains, densities, patterns...

3d DD Simulation & Experiment Comparison

Loading Stage ($\leq \sim 1\%$ Strain) Simulations & Experiment

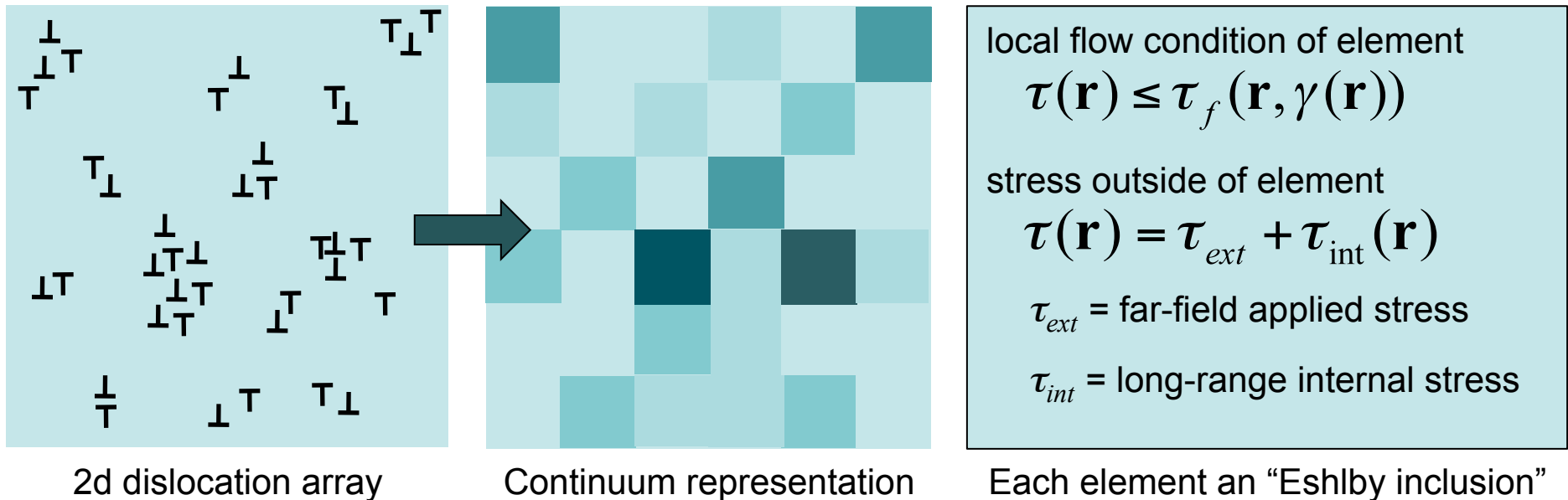


Exponent for strain burst size compares well to experiment for loading regime

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Continuum Mean Field Avalanche Theory



Element flow stress: $\tau_f(\mathbf{r}, \gamma(\mathbf{r})) = \delta\tau(\mathbf{r}, \gamma) + \tau_p(\mathbf{r})$ i.e. fluctuations & 'pile-up' stress

Correlation function of fluctuations: $\langle \delta\tau(\mathbf{r}, \gamma) \delta\tau(\mathbf{r} + \mathbf{r}', \gamma + \gamma') \rangle = \langle \delta\tau(\mathbf{r})^2 \rangle h(\mathbf{r}'/\xi) g(\gamma/\gamma_{corr})$

correlation lengths where $\xi \approx 1/\sqrt{\rho}$ & $\gamma_{corr} = b\rho\xi \approx b/\sqrt{\rho}$

Element flow condition:

$$\tau_{ext} + \tau_{int}(\mathbf{r}) + \frac{DG}{\rho} [\gamma_{xx} + \gamma_{yy}] + \delta\tau(\mathbf{r}, \gamma) > 0$$

Solved via CA simulation assumed Gaussian

External
Long-range internal
Pile-ups
Fluctuations (local density)

Stress Fluctuations and Scales

X-RAY DIFFRACTION

Close up on crystal plasticity

A novel X-ray diffraction technique opens the way to investigate deformation-induced dislocation microstructures with submicrometre resolution.

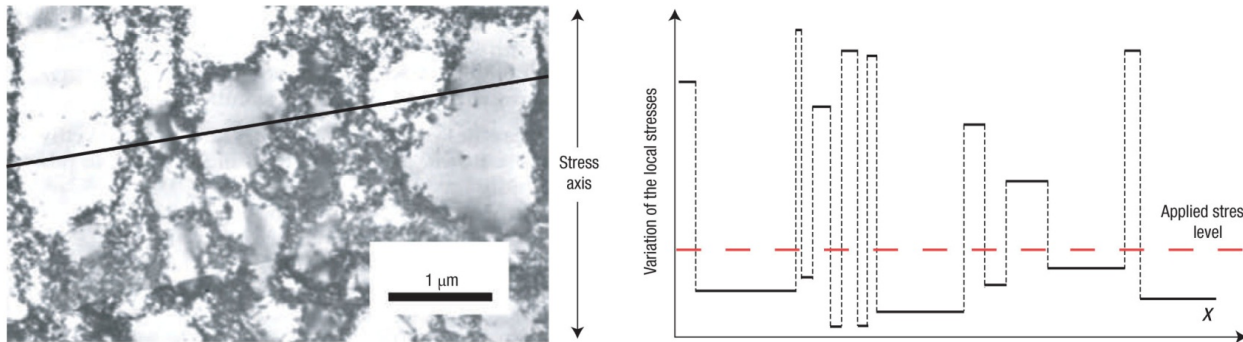


Figure 1 Correlation between the dislocation microstructure and the variation of the local long-range internal stresses in a tensile-deformed copper single-crystal. The TEM micrograph (bottom) reveals the dislocation cell structure. The regions with dark contrast correspond to dislocation cell walls encapsulating the cell-interior regions with light contrast, in which the number of dislocations is negligibly small. The stress axis is vertical in this figure. In the upper diagram, the value of the applied stress level is indicated as a horizontal red dashed line. The thick horizontal lines in the upper diagram represent the local stresses along the line shown in the TEM micrograph. In the cell-interior regions these local stresses are smaller, whereas in the cell-wall regions they are larger than the applied stress, as indicated in the figure. Although the local stress values fluctuate from region to region, they remain consistently lower or higher than the applied stress value in the cell interior and in the cell-wall regions, respectively. TEM image adapted from ref. 13; www.tandf.co.uk/journals.

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Mean Free Path or correlation length, multiple 'cells' ?

$$\sim 10 / \sqrt{\rho}$$

Characteristic length or 'cell' size ?

$$1 / \sqrt{\rho}$$

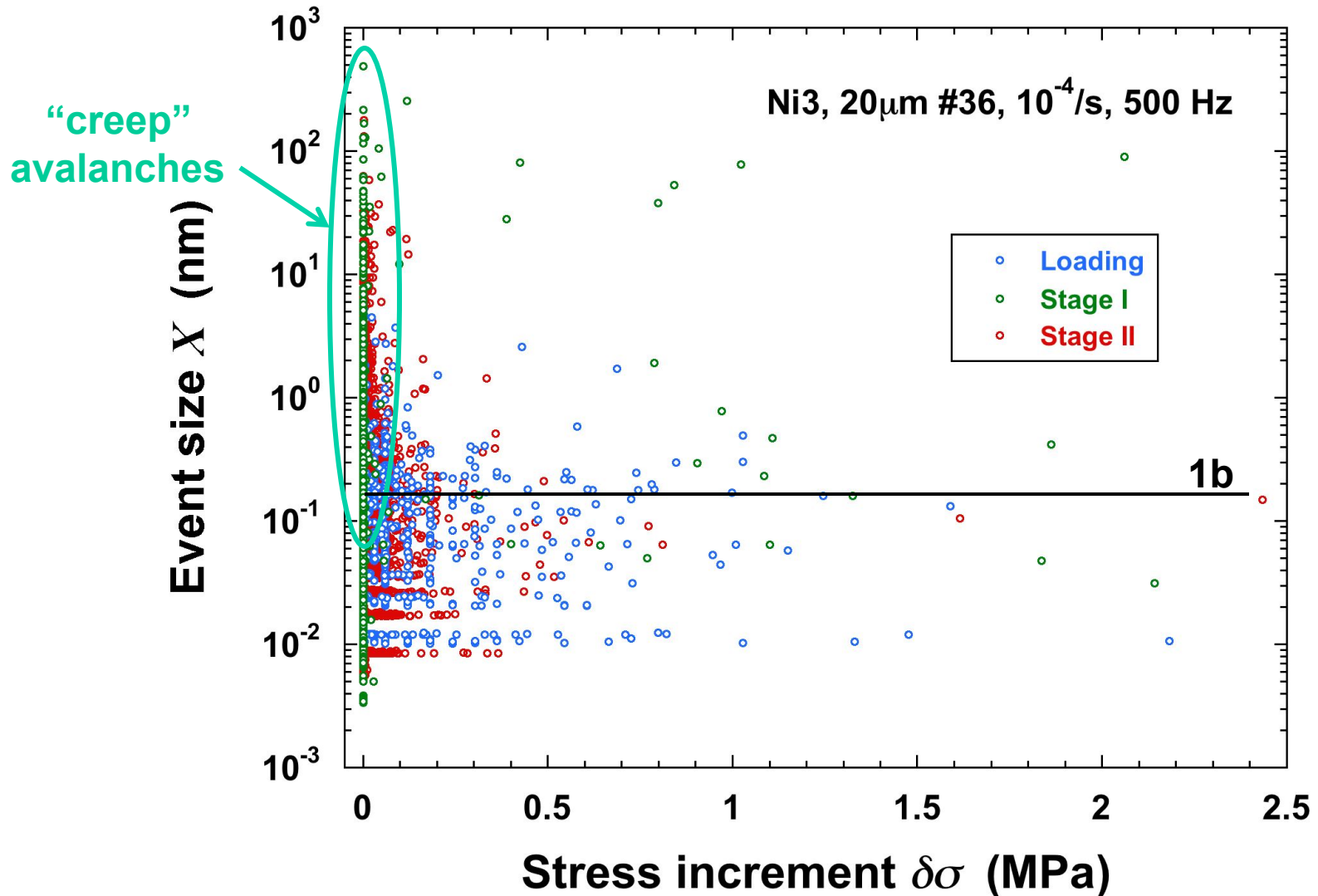
'Short Range' Interactions, 'cell' wall dimensions down to atomic (thermal activation)

Stress fluctuations on the order of the applied stress
Also at least 3 relevant length scales, at least 2 time scales...

Continuum Mean Field Avalanche Theory

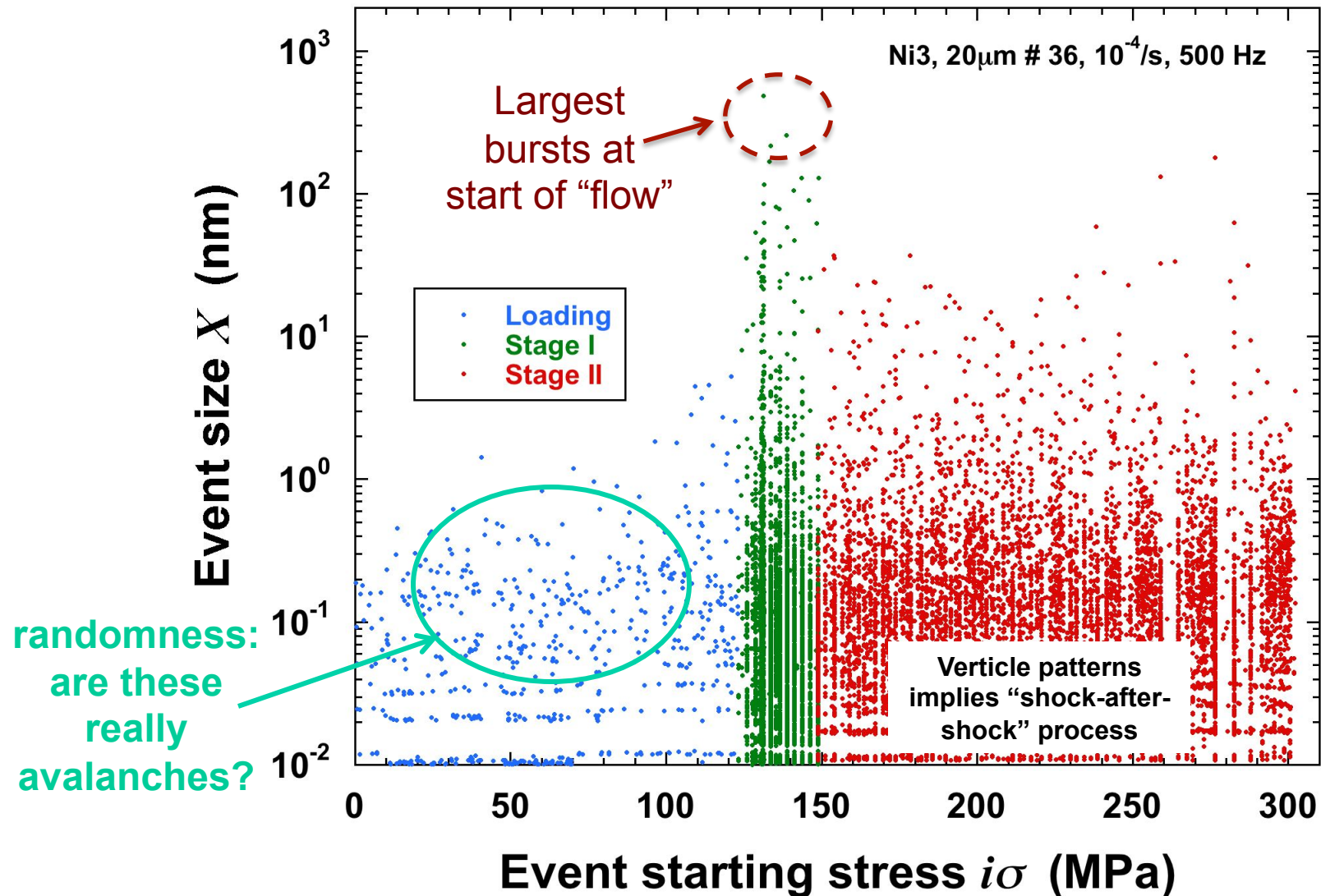
- 2d (infinite-line) Mean Field theory yields avalanche size probability scaling exponent of 1.5 & avalanche duration probability exponent of 2.0
- However, need studies of **at least three lengths scales**:
 - Effects of thermal activation & rate dependence (**short-range effects**)
 - 3d dislocation mechanisms (need to understand screening, interactions, anelastic effects, etc.)
 - Local dislocation statistics & their tie to screening & multiplication
 $\xi \approx 1/\sqrt{\rho}$, but $\xi \approx 10/\sqrt{\rho}$ estimate from *weak link* & classical theory
similar issue with γ_{corr} , should tie to trapping ('mean-free-path')
 $\delta\tau(\mathbf{r}, \gamma)$ may be power law, not Gaussian, but strain dependent
need to reconcile with Zaiser, Bay & Hahner, PRL (1998), Acta Mater. (1999) showing fractal substructure size distribution
 - Avalanches reflect dislocation multiplication (and hardening), i.e. time dependence & trapping probability
 $X_i \propto \delta(\rho_m v) \propto f(\tau_{loc}, \gamma_{loc})$ cross-slip probability, surface sources, etc.
 - Need to better understand temporal aspects of experimental methods

Stress change & burst size not well related



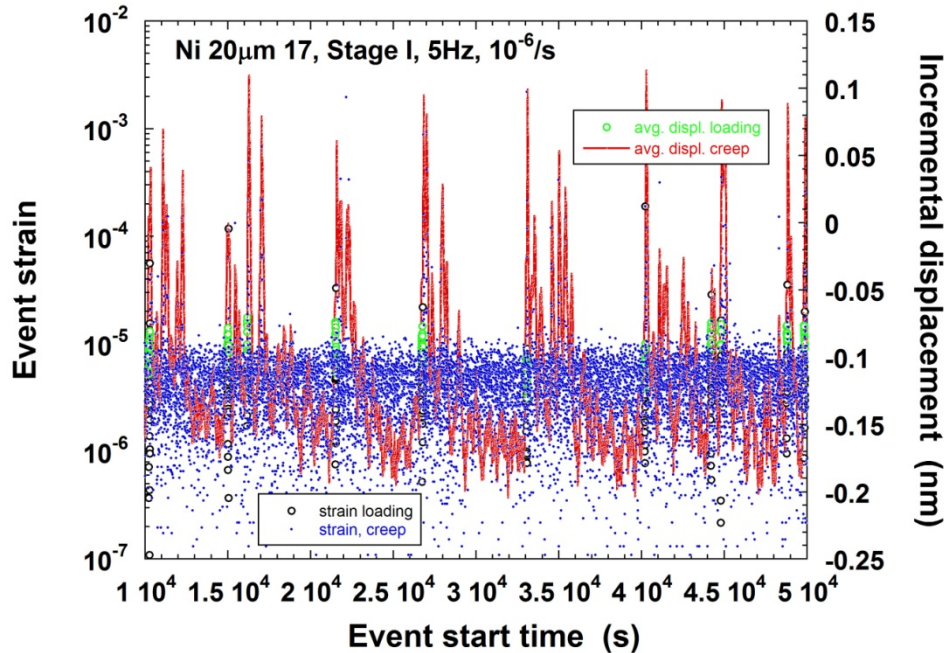
Many “creep” avalanches; dominated by internal stresses

Stress Level & Burst Size: Ni, $\rho_n \sim 10^{12}/m^2$

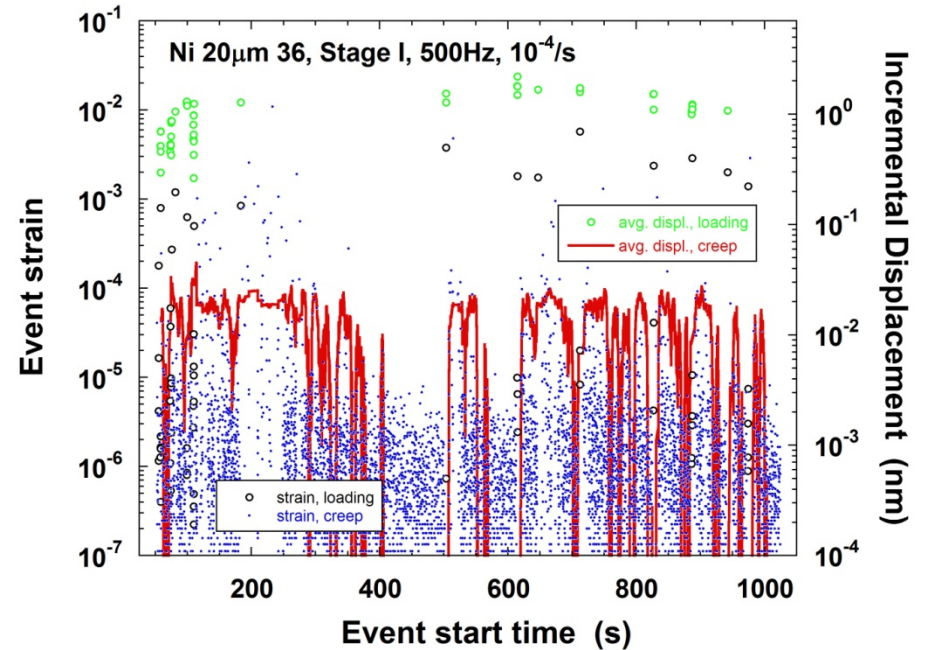


Clear influence of 'multiplication stress' & "trapping" probability (substructure)

Pure Ni: Displacements Between Strain Bursts



10^{-6} /s; Shock-Aftershock

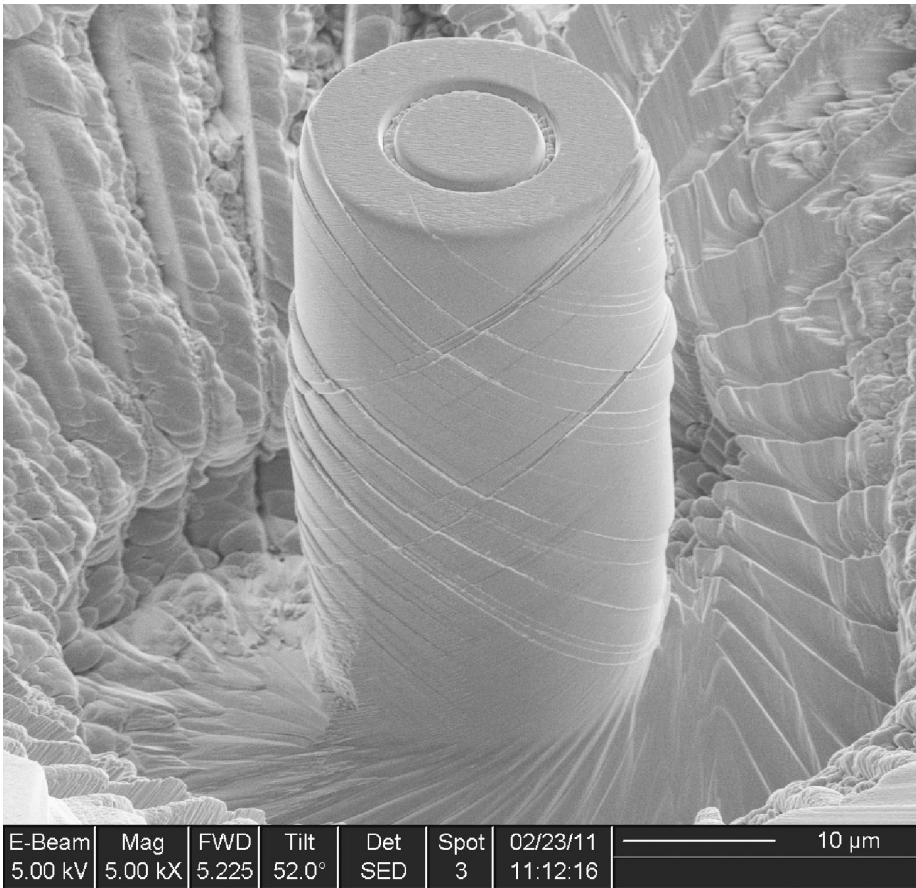


10^{-4} /s; Driven System

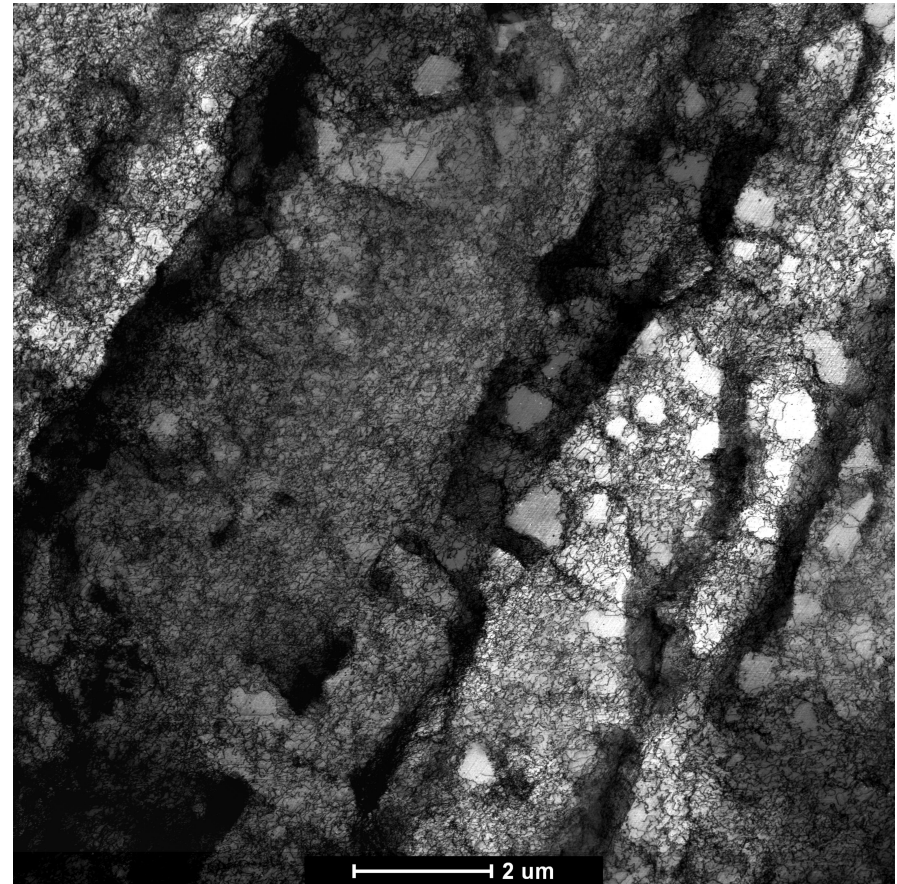
Perhaps only 10^{-6} /s testing has sufficient separation of driving - response scales

Other Current Studies

Pure Ni, $\langle 110 \rangle$ Oriented Bulk Crystal
Pre-Strained 26% into Stage III Flow



Additionally-strained
20 μ m microsample



Bulk Crystal Dislocations After Pre-Straining; $\sim \rho_0 \sim 10^{15}/\text{m}^2$

Synopsis About Intermittency

- *Loading Stage* (pre-yielding) and *Flow Stage* (large strain bursts)
- *Dislocation “multiplication” distinguishes the stages, strengthening & stress-sensitivity of mobile density*
- *Driving forces* are likely internal & long range
- *“Control” (& and scaling?) likely short range...*
- Largest observed “event” most affected by *strain hardening state*
 - The spatial-temporal aspects of the dislocation density (kinetics of weakest links)
 - The resolution of the measurement device relative to the obstacle landscape
 - Whiskers show huge events, LiF and Ni Stage I smaller, Ni Stage II smaller still, Stage 0 smallest, macroscopic stress-strain curves almost none at all...
- The *observed* power law *exponents are not universal*
 - Likely over-lapping avalanches for test conditions when mean-field value observed
 - Likely material & testing state parameter affected by multiplication & strain-hardening parameters; *stress sensitivity of mobile density*
 - Extensions to mean-field theory (dynamic, multiscale theory) required
- Strong correlation between size and duration implies *need for time resolution*
 - Need an *experimental system model*